TJA1085

FlexRay active star coupler

Rev. 2 — 7 March 2016 Product data sheet

1. General description

The TJA1085 is a FlexRay active star coupler that can connect up to 4 branches of a FlexRay network. The TJA1085 is compliant with the FlexRay electrical physical layer specification V3.0.1/ISO17458-4 (see Ref. 1 and Ref. 2).

Several TJA1085 devices can be connected via their TRXD0/1 interfaces to increase the number of branches in the network. A dedicated Communication Controller (CC) interface allows for integration into an ECU. The TJA1085 supports low-power management by offering bus wake-up capability along with battery supply and voltage regulator control. The TJA1085 meets industry standards for EMC/ESD performance and provides enhanced bus error detection, low current consumption and unmatched asymmetric delay performance.

The TJA1085 also fulfills the JASPAR requirements as defined by the Japanese car industry.

2. Features and benefits

2.1 General

- Compliant with FlexRay Electrical Physical Layer specification V3.0.1/ISO17458-4
- Fulfills JASPAR requirements
- Automotive product qualification in accordance with AEC-Q100
- Data transfer rates from 2.5 Mbit/s to 10 Mbit/s
- Supports 60 ns minimum bit time at 400 mV differential voltage
- Low-power management for battery-supplied ECUs
- Very low current consumption in AS_Sleep mode
- Leadless HVQFN44 package with improved Automated Optical Inspection (AOI) capability

2.2 Functional

- Supports autonomous active star operation independent of the host ensuring the TJA1085 remains active even if the host fails or is switched off
- Branches can be independently configured
- Branch extension via TRXD0/1 inner star interface
- 16-bit bidirectional SPI interface up to 2 Mbit/s for host communication
- Full host control over branch status
- Enhanced wake-up capability:
  - Remote wake-up via wake-up pattern and dedicated FlexRay data frames

- Local wake-up via pin LWU
- Wake-up source recognition
- configurable per branch

- Enhanced supply voltage monitoring on V_{IO}, V_{CC}, V_{BUF} and V_{BAT}
- Auto I/O level adaptation to host controller supply voltage V_{IO}
- Can be used in 14 V, 24 V and 48 V powered systems
- Enhanced bus error detection - detects short-circuit conditions on the bus
- Instant transmitter shut-down interface (BGE pin)
- Selective branch shut-down (partial networking)

2.3 Robustness

- Bus pins protected against ±8 kV ESD pulses according to HBM and ±6 kV ESD pulses according to IEC61000-4-2
- All pins protected against ±1000 V ESD according to CDM
- All pins protected against ±200 V ESD according to MM
- No reverse currents from the digital input pins to V_{IO} or V_{CC} when the TJA1085 is not powered up
- Bus pins short-circuit proof to battery voltage (14 V, 24 V or 48 V) and ground
- Overtemperature detection and protection
- Bus pins protected against transients in automotive environment (according to ISO 7637 class C)

2.4 Active star functional classes

- Active star - communication controller interface
- Active star - bus guardian interface
- Active star - voltage regulator control
- Active star - logic level adaptation
- Active star - host interface
- Active star - increased voltage amplitude transmitter

3. Ordering information

Table 1. Ordering information

Type number	Package		
	Name	Description	Version
TJA1085HN	HVQFN44	plastic thermal enhanced very thin quad flat package; no leads; 44 terminals; body 9 × 9 × 0.85 mm	SOT1113-1

4. Block diagram

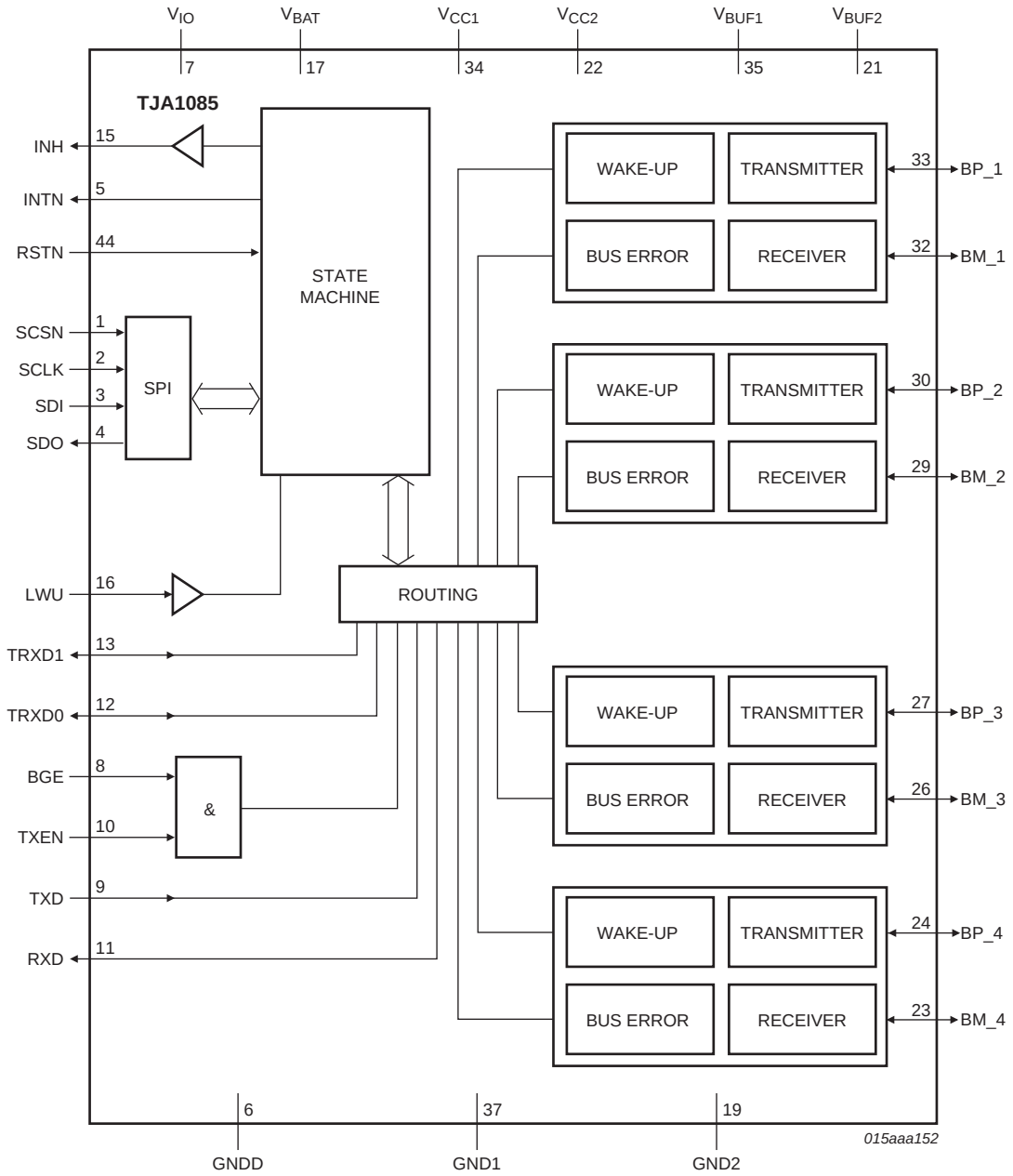
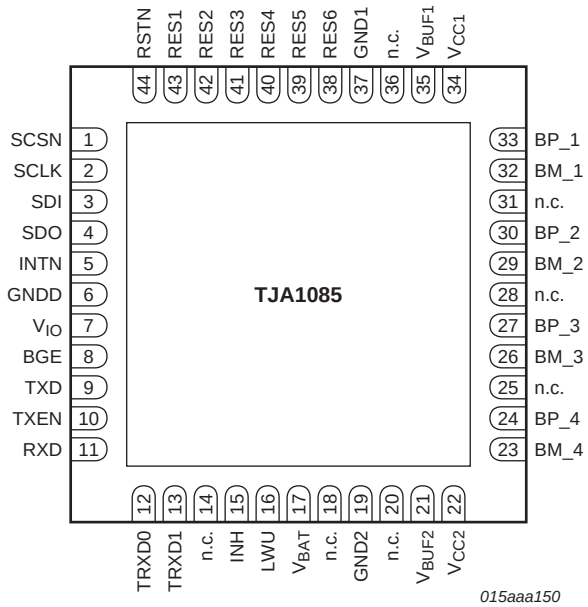


Fig 1. Block diagram

5. Pinning information

5.1 Pinning



Transparent top view

Fig 2. Pin configuration

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Type[1]	Description
SCSN	1	I	SPI chip select input; internal pull-up
SCLK	2	I	SPI clock signal; internal pull-down
SDI	3	I	SPI data input; internal pull-down
SDO	4	O	SPI data output; 3-state output
INTN	5	O	interrupt output; open-drain output, low-side driver
GNDD	6	G	ground for digital circuits[2]
V_{IO}	7	P	supply voltage for V_{IO} voltage level adaptation
BGE	8	I	bus guardian enable input; internal pull-down
TXD	9	I	transmit data input; internal pull-down
TXEN	10	I	transmitter enable input; internal pull-up
RXD	11	O	receive data output
TRXD0	12	IO	data bus line 0 for inner star connection
TRXD1	13	IO	data bus line 1 for inner star connection
n.c.	14	-	not connected; to be connected to GND in application
INH	15	O	inhibit output; for switching external voltage regulator

Table 2. Pin description *...continued*

Symbol	Pin	Type[1]	Description
LWU	16	I	local wake-up input; internal pull-up or pull-down (depends on voltage at pin LWU)
V_{BAT}	17	P	battery supply voltage
n.c.	18	-	not connected; to be connected to GND in application
GND2	19	G	ground connection for branches 3 and 4[2]
n.c.	20	-	not connected; to be connected to GND in application
V_{BUF2}	21	P	buffer supply voltage for branches 3 and 4[3]
V_{CC2}	22	P	supply voltage for branches 3 and 4[4]
BM_4	23	IO	bus line minus for branch 4[5]
BP_4	24	IO	bus line plus for branch 4[6]
n.c.	25	-	not connected; to be connected to GND in application
BM_3	26	IO	bus line minus for branch 3[5]
BP_3	27	IO	bus line plus for branch 3[6]
n.c.	28	-	not connected; to be connected to GND in application
BM_2	29	IO	bus line minus for branch 2[5]
BP_2	30	IO	bus line plus for branch 2[6]
n.c.	31	-	not connected; to be connected to GND in application
BM_1	32	IO	bus line minus for branch 1[5]
BP_1	33	IO	bus line plus for branch 1[6]
V_{CC1}	34	P	supply voltage for branches 1 and 2[4]
V_{BUF1}	35	P	buffer supply voltage for branches 1 and2[3]
n.c.	36	-	not connected; to be connected to GND in application
GND1	37	G	ground connection for branches 1 and 2[2]
RES6	38	-	reserved; to be connected to GND in application
RES5	39	-	reserved; to be connected to GND in application
RES4	40	-	reserved; to be connected to GND in application
RES3	41	-	reserved; to be connected to GND in application
RES2	42	-	reserved; to be connected to GND in application
RES1	43	-	reserved; to be connected to GND in application
RSTN	44	I	reset input; internal pull-up

[1] IO: input/output; O: output; I: input; P: power supply; G: ground.

[2] GND1, GND2, GNDD and the exposed center pad of HVQFN44 package must be connected together on the PCB; references in the data sheet to GND can be assumed to encompass GND1, GND2, GNDD and the exposed center pad of HVQFN4 unless stated otherwise.

[3] V_{BUF1} and V_{BUF2} must be connected together on the PCB; note that references in the data sheet to V_{BUF} can be assumed to encompass V_{BUF1} and V_{BUF2} unless stated otherwise.

[4] V_{CC1} and V_{CC2} must be connected together on the PCB; note that references in the data sheet to V_{CC} can be assumed to encompass V_{CC1} and V_{CC2} unless stated otherwise.

[5] References in the data sheet to BM (e.g. pin BM or V_{BM}) can be assumed to encompass BM_1, BM_2, BM_3 and BM_4 unless stated otherwise.

[6] References in the data sheet to BP (e.g. pin BP or V_{BP}) can be assumed to encompass BP_1, BP_2, BP_3 and BP_4 unless stated otherwise.

6. Functional description

6.1 Supply voltage

The TJA1085 state machine is adequately supplied if at least one of V_{BAT}, V_{CC} or V_{BUF} is available. The internal supply voltage to the state machine is denoted by V_{DIG}. V_{BUF} is an auxiliary supply and is only needed for forwarding the wake-up pattern when V_{CC} is not available.

6.2 Host Control (HC) and Autonomous Power (AP) modes - APM flag

The APM flag determines whether the TJA1085 is host-controlled or is operating in Autonomous Power mode. It is in AP mode by default.

The TJA1085 sets the APM flag:

- at power-on
- when a wake-up event is detected (on TXRD0/1, local or remote)
- when a V_{CC} undervoltage event is detected in AS_Normal mode
- when a V_{IO} undervoltage event lasts longer than $t_{to(uvd)(VIO)}$

The host can set or reset the APM flag at any time.

6.3 Signal router

The signal router transfers data received on an input channel to all channels configured as outputs. If data is being received on more than one input channel at the same time, the channel that was first to signal activity is selected and data on the other channel/s is ignored. Whether or not the data on an output channel is transmitted depends on whether the output channel is enabled or disabled.

The TJA1085 contains the following data input channels:

- Branches 1 to 4
- TRXD0/1 interface (inner star interface)
- TXD/TXEN interface

The TJA1085 contains the following data output channels:

- Branches 1 to 4
- TRXD0/1 interface
- RXD pin

6.3.1 TRXD collision

When the TRXD0/1 interface is configured as an output channel, a TRXD collision is detected (COLL_TRXD = 1) if pins TRXD0 and TRXD1 are both LOW for longer than $t_{det(col)(TRXD)}$, generating a CLAMP_ERROR interrupt.

When a TRXD collision is detected, the TJA1085 transmits a DATA_0 to all other active output channels (irrespective of the actual data on the selected input channel), until the selected input channel detects idle state.

6.4 Wake-up

The TJA1085 supports the following wake-up mechanisms:

- Remote wake-up via the bus (wake-up pattern or dedicated wake-up frame)
- Local wake-up via pin LWU
- Activity on the inner star interface (pins TRXD0 and TRXD1)

Any wake-up event will generate a WU interrupt. A remote wake-up on a branch will generate an EVENT_BRx interrupt to indicate the branch where the wake-up pattern or dedicated data frame was detected.

The host can identify the wake-up source by polling the General Status register (WU_TRXD = 1 for a TRXD0/1 wake-up; WU_LOCAL = 1 for a local wake-up) and the Branch Status register (WU_BRx = 1 for a remote wake-up).

6.4.1 Remote wake-up

When the TJA1085 is in AS_Standby or AS_Sleep, all branches are monitored for wake-up events. When a valid wake-up pattern or data frame is detected on a branch, the relevant WU_BRx status bit is set and the wake-up pattern/data frame is forwarded to all other enabled branches.

A remote wake-up event occurring during an AS_Normal-to-AS_Standby or AS_Normal-to-AS_Sleep transition will also be detected, setting the relevant WU_BRx status bit and generating WU and EVENT_BRx interrupts.

6.4.1.1 Bus wake-up via wake-up pattern

A wake-up pattern consists of at least two consecutive wake-up symbols. A wake-up symbol consists of a DATA_0 phase lasting longer than $t_{det(wake)DATA\_0}$, followed by an idle phase lasting longer than $t_{det(wake)idle}$, provided both wake-up symbols occur within a time span of $t_{det(wake)tot}$ (see Figure 3). The transceiver also wakes up if the idle phases are replaced by DATA_1 phases.

A wake-up event is not detected if an invalid wake-up pattern is received. See Ref. 1 for more details on invalid wake-up patterns.

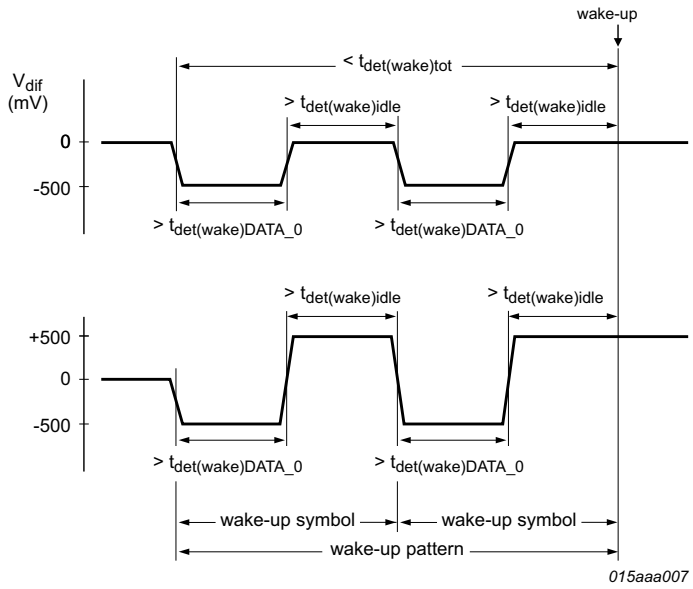


Fig 3. Bus wake-up timing

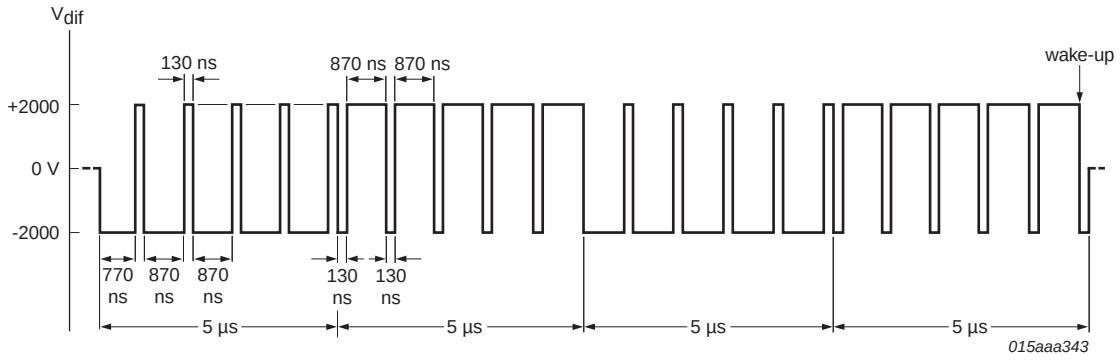
See Ref. 1 for more details of the wake-up mechanism.

6.4.1.2 Bus wake-up via dedicated FlexRay data frame

The TJA1085 detects a wake-up event when a dedicated data frame emulating a valid wake-up pattern, as shown in Figure 4, is received.

The Data_0 and Data_1 phases of the emulated wake-up symbol are interrupted by the Byte Start Sequence (BSS) preceding each byte in the data frame. With a data rate of 10 Mbit/s, the interruption has a maximum duration of 130 ns and does not prevent the transceiver from recognizing the wake-up pattern in the payload.

For longer interruptions at lower data rates (5 Mbit/s and 2.5 Mbit/s), the wake-up pattern should be used (see Section 6.4.1.1).



The duration of each interruption is 130 ns.

The transition time from DATA_0 to DATA_1 and vice versa is about 20 ns.

The TJA1085 wake-up flag is set on receipt of the following frame payload:

0xFF, 0xFF, 0xFF, 0xFF, 0xFF, 0x00, 0x00, 0x00, 0x00, 0x00,

0xFF, 0xFF, 0xFF, 0xFF, 0xFF, 0x00, 0x00, 0x00, 0x00, 0x00,

0xFF, 0xFF, 0xFF, 0xFF, 0xFF, 0x00, 0x00, 0x00, 0x00, 0x00,

0xFF, 0xFF, 0xFF, 0xFF, 0xFF, 0xFF

Fig 4. Minimum bus pattern for bus wake-up via dedicated FlexRay data frame

6.4.2 Local wake-up via pin LWU

Local wake-up is detected when the voltage on pin LWU is lower than $V_{th(wake)(LWU)}$ for longer than $t_{det(wake)(LWU)}$ (falling edge on pin LWU). When local wake-up is detected, the WU_LOCAL status bit is set and a WU interrupt is generated. At the same time, the internal biasing of this pin is switched to pull-down.

If the voltage on pin LWU rises and remains above $V_{th(wake)(LWU)}$ for longer than $t_{det(wake)(LWU)}$ (rising edge on pin LWU), local wake-up is not detected and the biasing on pin LWU is switched to pull-up.

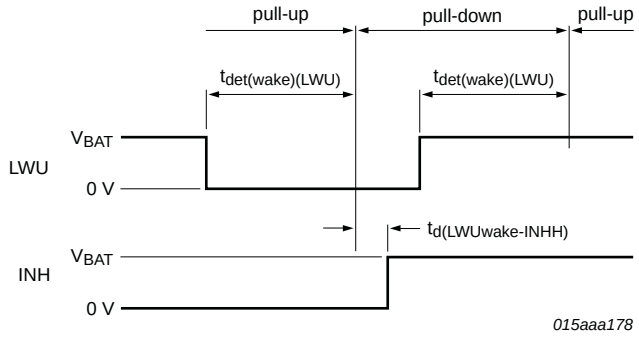


Fig 5. Local wake-up timing on pin LWU

6.4.3 Wake-up via the TRXD0/1 interface

If the voltage on pin TRXD0 or pin TRXD1 is LOW for longer than $t_{det(wake)(TRXD)}$, a WU interrupt is generated and the WU_TRXD status bit is set.

6.5 Communication controller interface

6.5.1 Bus activity and idle detection

The following mechanisms for activity and idle detection are valid in normal power modes:

- If the absolute differential voltage on the bus lines is higher than $|V_{i(dif)det(act)}|$ for $t_{det(act)(bus)}$, activity is detected on the bus lines
- If, after bus activity detection, the differential voltage on the bus lines is higher than $V_{IH(dif)}$, pin RXD will go HIGH
- If, after bus activity detection, the differential voltage on the bus lines is lower than $V_{IL(dif)}$, pin RXD will go LOW
- If the absolute differential voltage on the bus lines is lower than $|V_{i(dif)det(act)}|$ for $t_{det(idle)(bus)}$, then idle is detected on the bus lines (pin RXD is switched HIGH or remains HIGH)

Additionally, activity and idle can be detected:

- if pin TXEN is LOW for longer than $t_{det(act)(TXEN)}$, activity is detected on pin TXEN
- if pin TXEN is HIGH for longer than $t_{det(idle)(TXEN)}$, idle is detected on pin TXEN
- if pin TRXD0 or TRXD1 is LOW for longer than $t_{det(act)(TRXD)}$, activity is detected on the TRXD0/1 interface
- if pins TRXD0 and TRXD1 are both HIGH for longer than $t_{det(idle)(TRXD)}$, idle is detected on the TRXD0/1 interface

Table 3. Transmitter input signals: TXD, TXEN and BGE[1]

TXD	TXEN	BGE	V_{IO} UV detected	RXD	Bus	TRXD0	TRXD1	Operating mode
X	H	X	no	HIGH	idle	high ohmic[2]	high ohmic[2]	AS_Normal
X	X	L	no	HIGH	idle	high ohmic[2]	high ohmic[2]	AS_Normal
L	L	H	no	LOW	DATA_0	LOW	high ohmic[2]	AS_Normal
H	L	H	no	HIGH	DATA_1	high ohmic[2]	LOW	AS_Normal
X	X	X	no	HIGH	idle	high ohmic[2]	high ohmic[2]	AS_Standby,[3] AS_Sleep[3]
X	X	X	yes	LOW	idle	high ohmic[2]	high ohmic[2]	AS_Normal, AS_Standby,[3] AS_Sleep[3]
X	X	X	X	HIGH	float	high ohmic[2]	high ohmic[2]	AS_PowerOff, AS_Reset

[1] The transmitter is activated by a falling edge on pin TXD while TXEN is LOW and BGE is HIGH.

[2] Internal pull-up resistor (R_{pu}) to V_{BUF}.

[3] BP and BM biased to GND.

Table 4. Bus as input

Bus	V_{IO} UV detected	RXD	TRXD0	TRXD1	Operating mode
DATA_0	no	LOW	LOW	high ohmic[1]	AS_Normal
DATA_1	no	HIGH	high ohmic[1]	LOW	AS_Normal
idle	no	HIGH	high ohmic[1]	high ohmic[1]	AS_Normal
X	no	HIGH	high ohmic[1]	high ohmic[1]	AS_Standby, AS_Sleep

Table 4. Bus as input

Bus	V_{IO} UV detected	RXD	TRXD0	TRXD1	Operating mode
DATA_0	yes	LOW	LOW	high ohmic[1]	AS_Normal
DATA_1	yes	LOW	high ohmic[1]	LOW	AS_Normal
idle	yes	LOW	high ohmic[1]	high ohmic[1]	AS_Normal
X	yes	LOW	high ohmic[1]	high ohmic[1]	AS_Standby, AS_Sleep
X	X	HIGH	high ohmic[1]	high ohmic[1]	AS_PowerOff, AS_Reset

[1] Internal pull-up resistor (R_{pu}) to V_{BUF}.

Table 5. TRXD0/1 interface configured as input

TRXD0	TRXD1	V_{IO} UV detected	RXD	Bus	Operating mode
X	falling edge	no	HIGH	DATA_1	AS_Normal[1]
HIGH	HIGH	no	HIGH	idle	AS_Normal
falling edge	X	X	LOW	DATA_0	AS_Normal[1]
X	falling edge	yes	LOW	DATA_1	AS_Normal[1]
HIGH	HIGH	yes	LOW	idle	AS_Normal
LOW	LOW	X	LOW	DATA_0	collision detected on TRXD0/1

[1] Activity detected on TRXD0/TRXD1.

6.6 Bus error detection

The TJA1085 provides bus error detection on each branch during data transmission. When a transmit error (TxE_BRx = 1) is detected on a branch, an EVENT_BRx interrupt is generated to notify the host.

The following conditions trigger bus error detection:

- Short circuit BP to BM
- Short-circuit BP to GND
- Short-circuit BM to GND
- Short-circuit BP to V_{CC} or V_{BAT}
- Short-circuit BM to V_{CC} or V_{BAT}

6.7 Interrupt generation

Interrupts are generated when specific events take place or associated status bits in the General or Branch X status registers are set. When an interrupt is generated, the relevant interrupt status bit is set in the Interrupt Status register (see Table 9) and pin INTN is forced LOW.

Some interrupt status bits (PWON, WU, SPI_ERROR and HC_ERROR) are reset immediately after the Interrupt Status register has been read successfully (i.e. a rising edge on SCSN with no SPI_ERROR).

The UV_ERROR, CLAMP_ERROR, TEMP_ERROR and EVENT_BRx status bits are reset after the flag (or flags) that triggered the interrupt has been reset and a successful read operation had been performed (these two events can occur in any order). Resetting these bits triggers a further falling edge on INTN to indicate to the host that the issue that triggered the interrupt has been resolved (except in the case of EVENT_BRx if a branch wake-up event triggered the interrupt). See Section 6.10.2.3 for further details.

INTN signaling conforms to the FlexRay Electrical Physical Layer specification V3.0.1 (see Ref. 1).

6.8 Operating modes

The TJA1085 features five operating modes.

AS_PowerOff, AS_Sleep and AS_Standby are low-power modes in which the transceiver is unable to transmit or receive data streams on the bus. In AS_PowerOff mode, only power-on reset detection is active. The SPI, the low-power receiver and wake-up detection are active in AS_Sleep mode. Undervoltage detection is enabled on V_{CC}, V_{BAT} and V_{BUF} in AS_Standby and AS_Normal modes. V_{IO} undervoltage detection is always enabled, except when the TJA1085 is in AS_PowerOff mode.

In AS_Normal mode, the TJA1085 can transmit and receive data streams on the bus.

Pin INH is HIGH in AS_Normal, AS_Standby and AS_Reset, and floating in AS_PowerOff and AS_Sleep.

The dStarGoToSleep timer is started when the TJA1085 switches to AS_Standby or AS_Normal, or when idle is detected on the bus. The timer is halted and reset when activity is detected on the bus.

6.8.1 Operating mode transitions

6.8.1.1 AS_PowerOff

The TJA1085 switches to AS_PowerOff from any mode if the internal supply to the state machine, V_{DIG}, falls below the power-on detection threshold voltage ($V_{th(det)POR}$). It remains in AS_PowerOff until V_{DIG} rises above the power-on recovery threshold voltage ($V_{th(rec)POR}$), when it switches to AS_Standby. Pins INTN and SDO are switched to a high-impedance state in AS_PowerOff mode.

6.8.1.2 AS_Reset

The TJA1085 switches to AS_Reset from any mode if pin RSTN goes LOW with no undervoltage detected on V_{IO}. It remains in AS_Reset until pin RSTN goes HIGH, when it switches to AS_Standby.

6.8.1.3 AS_Standby

The TJA1085 switches to AS_Standby:

- from AS_PowerOff when V_{DIG} rises above the power-on recovery threshold voltage ($V_{th(rec)POR}$)
- from AS_Reset when pin RSTN goes HIGH
- from AS_Normal when a V_{CC} undervoltage event is detected ($V_{CC} < V_{uvd(VCC)}$ for longer than $t_{det(uv)(VCC)}$)

- from AS_Normal in response to a host ‘AS_Standby’ command (HC mode)
- from AS_Sleep in response to a host ‘AS_Standby’ command (HC mode)
- from AS_Sleep when a wake-up event is detected

The TJA1085 switches from AS_Standby:

- to AS_Normal when a wake-up event is detected, provided $V_{BUF} > V_{uvr(VBUF)}$
- to AS_Normal when a V_{CC} undervoltage recovery event is detected ($V_{CC} > V_{uvr(VCC)}$ for longer than $t_{rec(uv)(VCC)}$), provided $V_{BUF} > V_{uvr(BUF)}$
- to AS_Normal in response to a host ‘AS_Normal’ command (HC mode)
- to AS_Sleep if the dStarGoToSleep timer expires (AP mode)
- to AS_Sleep if a V_{CC} undervoltage event lasts longer than $t_{to(uvd)(VCC)}$ (HC mode)
- to AS_Sleep in response to a host ‘AS_Sleep’ command (HC mode)

6.8.1.4 AS_Sleep

A wake-up event will trigger a transition to AS_Standby (followed by a transition to AS_Normal if $V_{BUF} > V_{uvr(VBUF)}$).

The TJA1085 switches to AS_Sleep:

- from AS_Standby in response to a host ‘AS_Sleep’ command (HC mode)
- from AS_Standby if the dStarGoToSleep timer expires (AP mode)
- from AS_Standby if a V_{CC} undervoltage event lasts longer than $t_{to(uvd)(VCC)}$ (HC mode)
- from AS_Normal in response to a host ‘AS_Sleep’ command (HC mode)
- from AS_Normal if the dStarGoToSleep timer expires (AP mode)

The TJA1085 switches from AS_Sleep:

- to AS_Standby in response to a host ‘AS_Standby’ command (HC mode)
- to AS_Standby when a wake-up event is detected.
- to AS_Normal in response to a host ‘AS_Normal’ command (HC mode)

6.8.1.5 AS_Normal

The TJA1085 switches to AS_Normal:

- from AS_Standby if a V_{CC} undervoltage recovery event is detected ($V_{CC} > V_{uvr(VCC)}$ for longer than $t_{rec(uv)(VCC)}$), provided $V_{BUF} > V_{uvr(BUF)}$
- from AS_Standby if a wake-up event is detected, provided $V_{BUF} > V_{uvr(VBUF)}$ for longer than $t_{rec(uv)(VBUF)}$
- from AS_Standby or AS_Sleep in response to a host ‘AS_Normal’ command

The TJA1085 switches from AS_Normal:

- to AS_Standby when a V_{CC} undervoltage event is detected ($V_{CC} < V_{uvd(VCC)}$ for longer than $t_{det(uv)(VCC)}$)

  - if the TJA1085 is in HC mode, it will switch from AS_Standby to AS_Sleep if the V_{CC} undervoltage persists for longer than $t_{to(uvd)(VCC)}$
  - if the TJA1085 is in AP mode, it will switch to AS_Sleep when the dStarGoToSleep timer expires

- to AS_Standby in response to a host ‘AS_Standby’ command (HC mode)
- to AS_Sleep in response to a host ‘AS_Sleep’ command (HC mode)
- to AS_Sleep if the dStarGoToSleep timer expires (AP mode)

6.8.1.6 Operating mode transition diagram

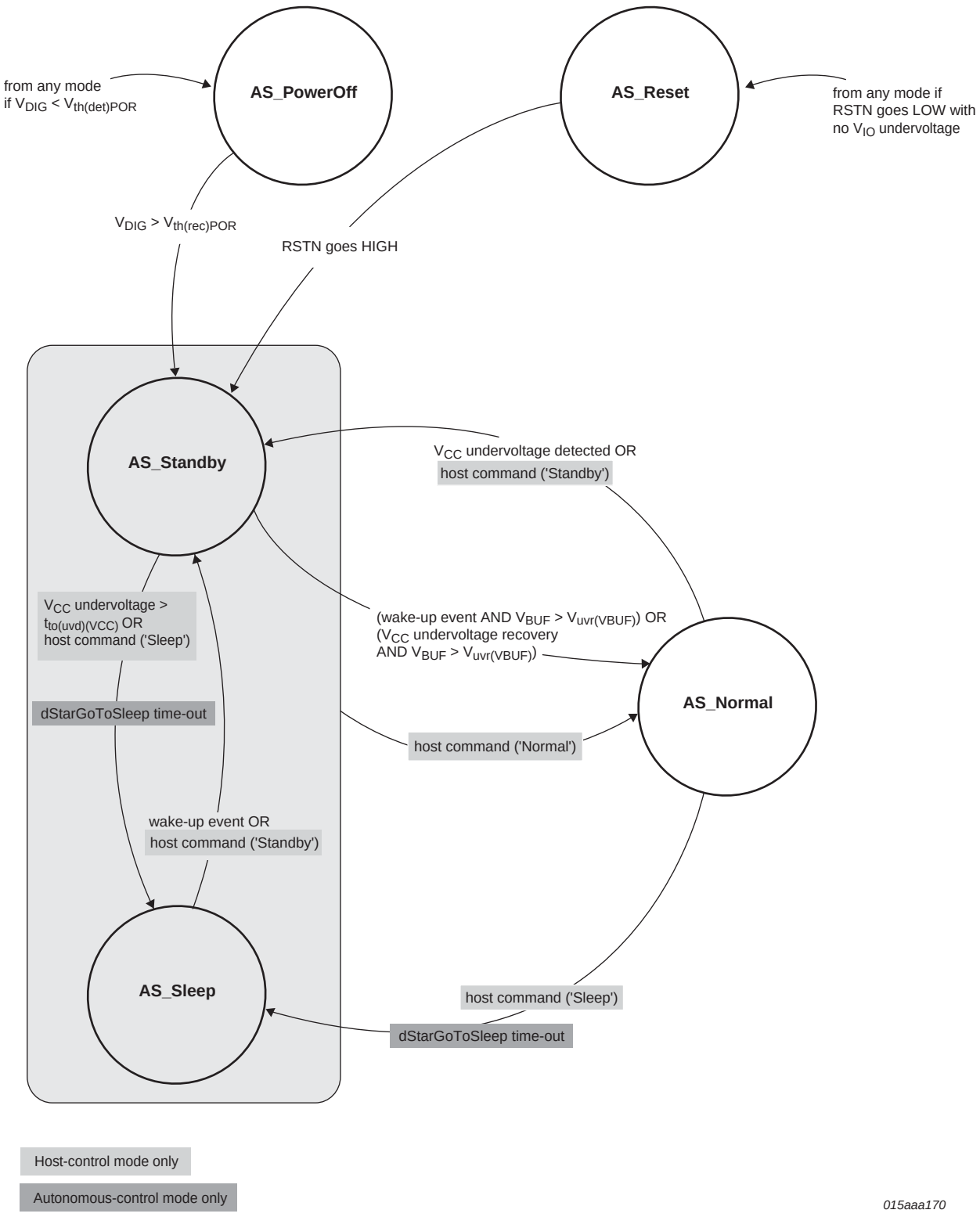


Fig 6. Mode transition diagram

6.9 Branch operating modes

Each of the four branches in the TJA1085 features six branch operating modes:

- Branch_Off
  All branches are in Branch_Off mode when the TJA1085 is in AS_PowerOff or AS_Reset mode. The transmitter, normal receiver, low-power receiver and bus error detection are disabled. The bus pins are floating.
- Branch_LowPower
  All branches are in Branch_LowPower mode when the TJA1085 is in AS_Standby or AS_Sleep mode. The transmitter, the normal receiver and bus error detection are disabled. The low-power receiver is active (i.e. remote wake-up is possible). The bus pins are biased to ground.
- Branch_Disabled
  The TJA1085 switches to Branch_Disabled if an overtemperature is detected. The 'Branch_Disabled' and 'Branch_Normal' commands allow the host to enable/disable a branch without affecting the remaining branches. The transmitter, normal receiver and bus error detection are disabled. Only the low-power receiver is active (remote wake-up is possible). The bus pins are biased to $V_{o(idle)(BP)}$ and $V_{o(idle)(BM)}$.
- Branch_Normal
  When a branch is in Branch_Normal, the TJA1085 will be in AS_Normal. The transmitter, normal receiver and bus error detection are active. The bus pins are biased to $V_{o(idle)(BP)}$ and $V_{o(idle)(BM)}$.
- Branch_TxOnly1
  In Branch_TxOnly1 mode, the receiver is disabled, i.e. the received data is not forwarded to the signal router. The transmitter is active and bus error detection is active. The bus pins are biased to $V_{o(idle)(BP)}$ and $V_{o(idle)(BM)}$.
- Branch_TxOnly2
  This mode is host-controlled only and is operationally identical to Branch_TxOnly1. It allows the host to switch off the receiver in response to error conditions.
- Branch_FailSilent
  The transmitter, the low-power receiver and bus error detection are disabled. Only the receiver remains active to monitor the branch for idle or activity. Received data is not forwarded to the signal router. The bus pins are biased to $V_{o(idle)(BP)}$ and $V_{o(idle)(BM)}$.

6.9.1 Branch operating mode transitions

Branch-related host commands can only be issued when the TJA1085 is in AS_Normal mode.

6.9.1.1 Branch_Off

When the TJA1085 enters AS_PowerOff or AS_Reset, all four branches switch to Branch-Off. When the TJA1085 subsequently switches to AS_Standby, all four branches switch to Branch_LowPower.

6.9.1.2 Branch_LowPower

All four branches switch to Branch_LowPower when the TJA1085 enters AS_Standby or AS_Sleep. All branches remain in this mode until the TJA1085 enters AS_Normal. When this transition happens, branches that were in Branch_Disabled before switching to Branch_LowPower return to Branch_Disabled. The remaining branches switch to Branch_Normal.

6.9.1.3 Branch_Disabled

An overtemperature event (TEMP_HIGH flag set) triggers a transition from Branch_Normal to Branch_Disabled in all branches.

If an overtemperature event triggered the transition from Branch_Normal to Branch_Disabled, all branches return to Branch_Normal when the overtemperature problem has been resolved (TEMP_WARN flag reset).

The ‘Branch_Disabled’ and ‘Branch_Normal’ commands can be used to enable/disable individual branches. A host command is also available to trigger a transition from Branch_Disabled to Branch_TxOnly1 (‘Branch_TxOnly').

If a branch switches from Branch_Disabled to Branch_LowPower because the TJA1085 has entered AS_Standby or AS_Sleep, it will return to Branch_Disabled when the TJA1085 enters AS_Normal.

6.9.1.4 Branch_FailSilent

A branch switches to Branch_FailSilent:

- from Branch_Normal if a branch is clamped (Clamp_BRx flag set), provided clamp-detection is enabled (bit CLAMP_DET set; see Table 8)
- from Branch_Normal if a transmit error (TxE_BRx = 1) is detected, provided autonomous error confinement is enabled (bit AEC set; see Table 8)
- from Branch_TxOnly1 if a transmit error (TxE_BRx = 1) is detected.

The branch remains in Branch_FailSilent until idle is detected on all branches, when it switches to Branch_TxOnly1 (a ‘Branch_TxOnly’ command is needed in HC mode).

6.9.1.5 Branch_TxOnly1

A branch switches to Branch_TxOnly1:

- from Branch_Disabled in response to a ‘Branch_TxOnly’ command (HC mode)
- from Branch_FailSilent in response to a ‘Branch_TxOnly’ command when all branches are idle (HC mode)
- from Branch_FailSilent when all branches are idle (AP mode)

A branch switches from Branch_TxOnly1:

- to Branch_Normal when a transmission ends without error
- to Branch_FailSilent if a transmit error is detected (TxE_BRx = 1)

6.9.1.6 Branch_TxOnly2

This mode is purely host controlled. A branch switches to Branch_TxOnly2 only in response to a ‘Branch_TxOnly’ command issued in Branch_Normal mode. The branch remains in Branch_TxOnly2 mode until a ‘Branch_Normal’ command is received.

6.9.1.7 Branch_Normal

A branch switches to Branch_Normal:

- from Branch_LowPower when the TJA1085 enters AS_Normal mode (provided it was not in Branch_Disabled before the transition to Branch_LowPower mode)

- from Branch_TxOnly2 in response to a host ‘Branch_Normal’ command
- from Branch_TxOnly1 when a transmission ends without error
- from Branch_Disabled in response to a host ‘Branch_Normal’ command
- from Branch_Disabled when an overtemperature is resolved (TEMP_WARN = 0), provided the overtemperature triggered the earlier transition to Branch_Disabled.

A branch switches from Branch_Normal:

- to Branch_FailSilent if a branch is clamped, provided clamp-detection is enabled (CLAMP_DET = 1)
- to Branch_FailSilent if a transmit error is detected, provided bit AEC = 1
- to Branch_TxOnly2 if a host ‘Branch_TxOnly’ command is received
- to Branch_Disabled if an overtemperature event is detected (TEMP_HIGH = 1)

6.9.1.8 Branch operating mode transition diagram

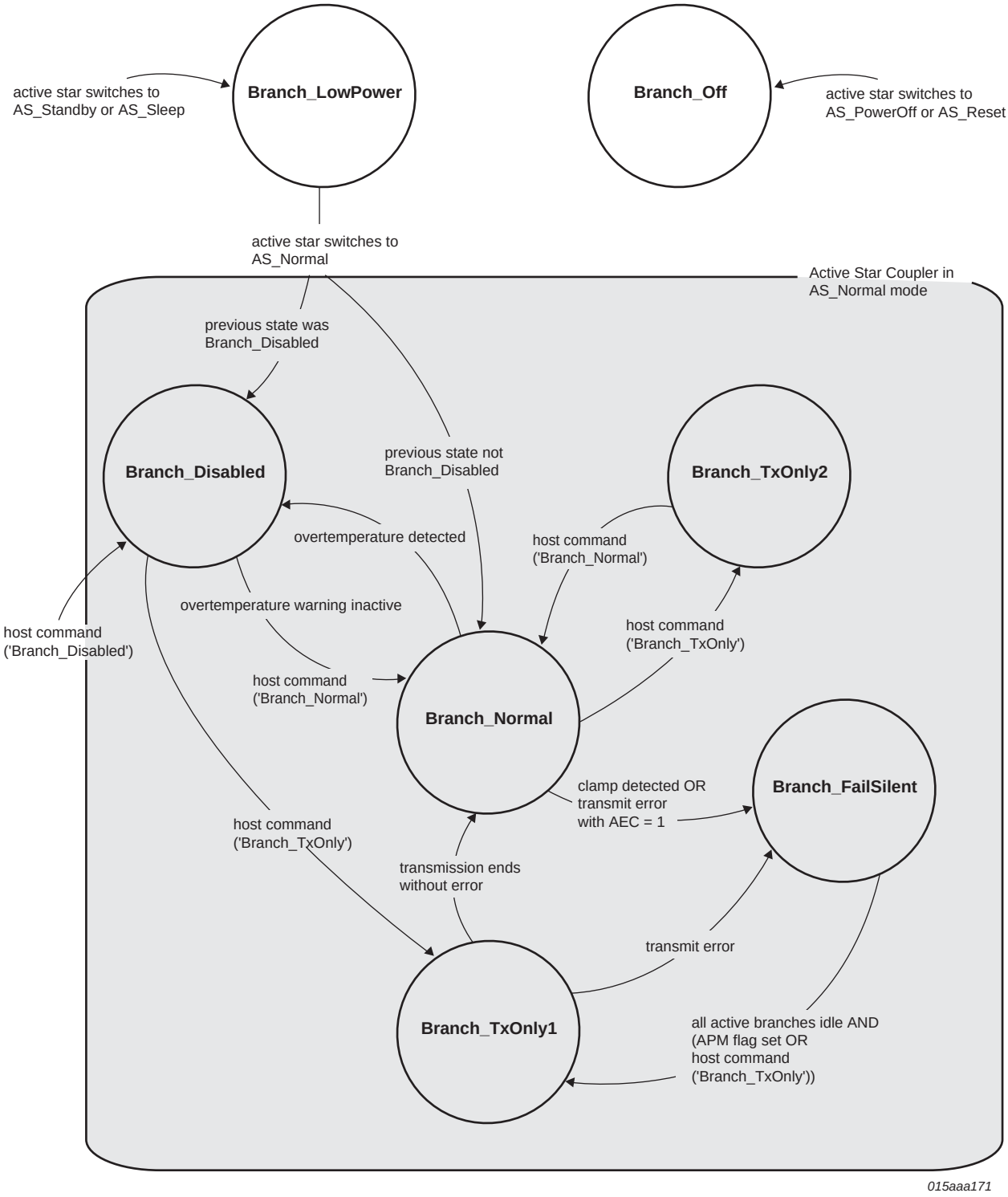


Fig 7. Branch mode transition diagram

6.10 SPI interface

The TJA1085 contains a bidirectional 16-bit Serial Peripheral Interface (SPI) for communicating with a host. The SPI allows the host to configure the TJA1085 and to access error and status information.

6.10.1 Register access

The SPI supports full duplex data transfer, so status information is read out on pin SDO while control data is being shifted in on pin SDI. Bit sampling is performed on the falling edge of the clock signal on pin SCLK and data is shifted on the rising edge (MSB first; see Figure 8).

The clock signal must be LOW when SCSN goes LOW to initiate an SPI register access cycle.

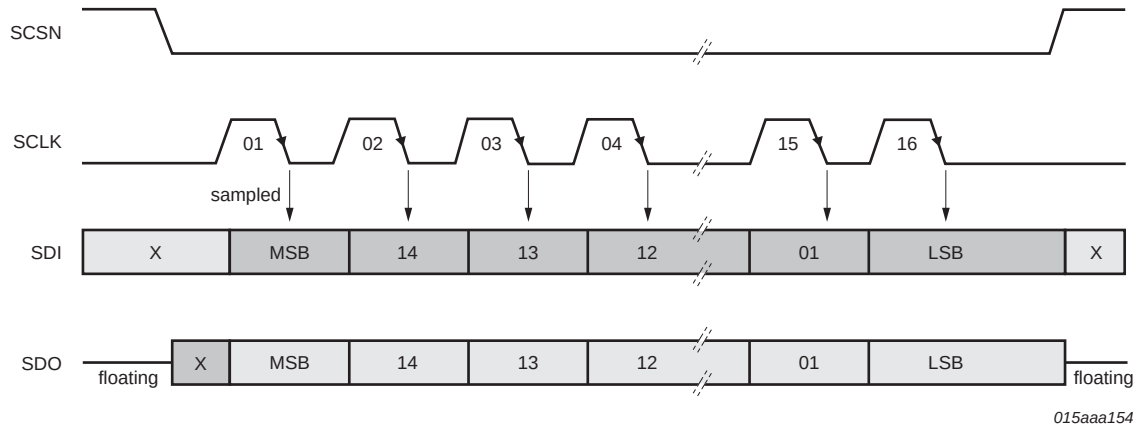


Fig 8. SPI register access

6.10.2 SPI registers

The SPI register structure in the TJA1085 is illustrated in Figure 9. The three MSBs (bits15 to 13) contain the 3-bit register address. Bit 12 defines the selected register access as read/write or read only. If bit 12 is 1, the SPI data transfer will be read only and all data on the SDI pin will be ignored. If bit 12 is 0, data bits 11 to 0 will be written to the selected register.

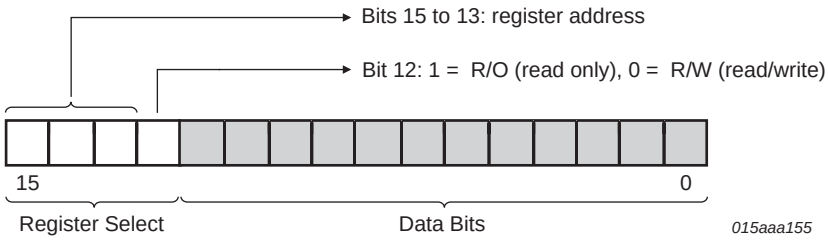


Fig 9. SPI register structure

The assignment of control and status register addresses is detailed in Table 6. Data can only be written to the Control and Configuration registers (status registers are read-only by definition). Therefore the state of bit 12 is only evaluated when these registers are being accessed.

Table 6. Register map

Address bits 15, 14 and 13	Write access bit 12[1]	Register
000	0 =R/W, 1 = R/O	Control register; see Table 7
001	1 = R/O	Interrupt status register; see Table 9
010	1 = R/O	General status register; see Table 10
011	1 = R/O	Branch 1 status register; see Table 11
100	1 = R/O	Branch 2 status register; see Table 11
101	1 = R/O	Branch 3 status register; see Table 11
110	1 = R/O	Branch 4 status register; see Table 11
111	0 =R/W, 1 = R/O	Configuration register; see Table 8

[1] Bit 12 is assumed to be 1 for status registers

The following subsections provide details of the bits in these registers and the control and status functionality assigned to each.

6.10.2.1 Control register

The read/write Control register allows the host controller to set the operating modes and to switch the TJA1085 between HC and AP modes.

Table 7. Control register bit description

Bit	Symbol	Access	Default	Description
11:10	OPM	R/W	00	operating mode:
				00: no change
				01: AS_Standby
				10: AS_Sleep
				11: AS_Normal
9:8	CTRL_BR1	R/W	00	branch 1 control:
				00: no change
				01: Branch_Normal
				10: Branch_TxOnly
				11: Branch_Disabled
7:6	CTRL_BR2	R/W	00	branch 2 control:
				00: no change
				01: Branch_Normal
				10: Branch_TxOnly
				11: Branch_Disabled
5:4	CTRL_BR3	R/W	00	branch 3 control:
				00: no change
				01: Branch_Normal
				10: Branch_TxOnly
				11: Branch_Disabled
3:2	CTRL_BR4	R/W	00	branch 4 control:
				00: no change
				01: Branch_Normal
				10: Branch_TxOnly
				11: Branch_Disabled
1	APM[1]	R/W	1	Autonomous Power mode
				0: disabled
				1: enabled
0	RESET_ERROR[2]	R/W	0	reset error flags and status bits
				0: no change
				1: reset flags/bits

[1] The TJA1085 sets the APM flag at power-on, in response to a wake-up event (local, remote or TRXD), if a V_{CC} undervoltage is detected in AS_Normal or a V_{IO} undervoltage is detected for longer than $t_{to(uvd)(VIO)}$.

[2] Setting the RESET_ERROR bit resets all error status bits in the General Status (bits 8 to 1) and Branch Status registers (bits 7 to 4).

6.10.2.2 Configuration register

The read/write Configuration register allows the host controller to configure a number of TJA1085 parameters and functions.

Table 8. Configuration register bit description

Bit	Symbol	Access	Default	Description
11	AEC	R/W	0	Autonomous error confinement:
				0: disabled
				1: enabled
10	BFT	R/W	1	Bus failure timer
				0: disabled
				1: enabled
9	WUD_BR1	R/W	1	wake-up detection on branch 1:
				0: disabled
				1: enabled
8	WUD_BR2	R/W	1	wake-up detection on branch 2:
				0: disabled
				1: enabled
7	WUD_BR3	R/W	1	wake-up detection on branch 3:
				0: disabled
				1: enabled
6	WUD_BR4	R/W	1	wake-up detection on branch 4:
				0: disabled
				1: enabled
5	CC_EN	R/W	0	CC interface enable (TXD and TXEN inputs; RXD output):
				0: disabled
				1: enabled
4	TRXD_EN	R/W	1	TRXD interface enable:
				0: disabled
				1: enabled
3	reserved			always 0
2	CLAMP_DET	R/W	1	clamping detection:
				0: disabled
				1: enabled
1	BIT_LATCHING	R/W	0	status bit latching:
				0: disabled
				1: enabled
0	PARITY	R	-	parity bit - odd parity (including parity bit)

Autonomous Error Confinement (AEC):
Setting the AEC bit enables the autonomous error confinement feature of the TJA1085.

When AEC is enabled, a bus error (TxE_BRx = 1) triggers a transition from Branch_Normal to Branch_FailSilent. AEC is disabled by default.

Bus Failure Timer (BFT):
Setting the BFT bit enables the bus failure timer.

When the BFT is enabled, pulses shorter than $t_{to(BFT)}$ are ignored, resulting in more robust bus error detection. The BFT is enabled by default.

Wake-up detection on branch x (WUD_BRx):
Setting the WUD_BRx bit enables wake-up detection on the specified branch.

Each branch in a TJA1085 star network contains a low-power receiver for detecting remote wake-up events. These events can be enabled and disabled individually. This feature makes it possible to minimize quiescent current consumption, especially in AS_Sleep mode. Wake-up detection is enabled by default on all branches.

Communication Controller interface Enable (CC_EN):
Setting bit CC_EN enables the communication controller interface.

A communication controller can be connected to the TJA1085 when CC_EN = 1. If CC_EN = 0, the RXD output driver is switched off to minimize current consumption in AS_Normal mode. The CC interface is disabled by default.

TRXD0/1 interface Enable (TRXD_EN):
Setting bit TRXD_EN enables the TRXD0 and TRXD1 interfaces.

When the TRXD0/1 interfaces are enabled, several TJA1085 devices can be connected together to form a single active star. If only one TJA1085 is needed at any time, the TRXD0/1 interfaces can be disabled to minimize current consumption in AS_Normal mode. The TRXD0 and TRXD1 interfaces are enabled by default.

Clamp detection (CLAMP_DET):
Setting bit CLAMP_DET enables clamp detection on TXEN, TRXD and on the four branches.

When clamp detection is enabled, a CLAMP_ERROR interrupt is generated if clamping is detected on TXEN (CLAMP_TXEN = 1), TRXD (CLAMP_TRXD = 1) or on a branch (CLAMP_BRx). Clamp detection is enabled by default.

Bit latching (BIT_LATCHING):
When bit latching is enabled (BIT_LATCHING = 1), the status bits in the General and Branch X status registers reflect the latched state until the register is read. Once the register has been read, latching is released and the bits then reflect the current ‘live’ status. When bit latching is disabled, the status bits reflect the ‘live’ status at all times. Bit latching is disabled by default.

6.10.2.3 Interrupt Status register

The Interrupt Status register is read-only. When the TJA1085 sets a bit in this register, it triggers a falling edge on pin INTN. Bits PWON, WU, SPI_ERROR and HC_ERROR are reset after a successful read operation. The remaining bits are reset after the flag (or flags) that triggered the interrupt has been reset and a successful read operation has been performed (see Section 6.7).

Table 9. Interrupt status register

Bit	Symbol	Description
11	PWON	power-on detection:
		0: no power-on detected
		1: power-on detected
10	WU	wake-up event detection (any):
		0: no wake-up event detected
		1: wake-up event detected
9	EVENT_BR1	wake-up or bus error detection on branch 1:
		0: no wake-up or bus error detected
		1: wake-up or bus error detected
8	EVENT_BR2	wake-up or bus error detection on branch 2:
		0: no wake-up or bus error detected
		1: wake-up or bus error detected
7	EVENT_BR3	wake-up or bus error detection on branch 3:
		0: no wake-up or bus error detected
		1: wake-up or bus error detected
6	EVENT_BR4	wake-up or bus error detection on branch 4:
		0: no wake-up or bus error detected
		1: wake-up or bus error detected
5	UV_ERROR	undervoltage detected on V_{BAT}, V_{CC} or V_{IO}:
		0: no undervoltage detected
		1: undervoltage detected
4	CLAMP_ERROR	clamp error on TRXD, TXEN or branch or collision on TRXD:
		0: no clamping error detected
		1: clamping error detected
3	SPI_ERROR	SPI communication error:
		0: not detected
		1: detected
2	HC_ERROR	host command error:
		0: not detected
		1: detected
1	TEMP_ERROR	overtemperature error:
		0: not detected
		1:detected
0	PARITY	parity bit - odd parity (including parity bit)

PWON: A PWON interrupt is generated to signal a power-on event.

The PWON interrupt status bit is set when the TJA1085 leaves AS_PowerOff or AS_Reset. It is reset after a successful read operation on the Interrupt Status register.

WU: A WU interrupt indicates the occurrence of a wake-up event.

The WU interrupt status bit is set when a wake-up event is detected on a branch (WU_BRx = 1), on TRXD0/1 (WU_TRXD = 1), or on LWU (WU_LOCAL = 1). It is reset after a successful read operation on the Interrupt Status register.

EVENT_BRx: An EVENT_BRx interrupt signals the occurrence of a significant event on the relevant branch.

The EVENT_BRx interrupt status bit is set when any of the following events is detected on a branch:

- a wake-up event (WU_BRx = 1)
- a bus error (TxE_BRx = 1)
- clamping (CLAMP_BRx = 1)

It is reset after the flag (or flags) that triggered the interrupt has been reset and the Interrupt Status register has been read successfully. Resetting EVENT_BRx will trigger a falling edge on INTN to indicate to the host that the event that triggered the interrupt has been resolved (except when the interrupt was triggered by a branch wake-up event).

UV_ERROR: A UV_ERROR interrupt indicates that an undervoltage has occurred.

The UV_ERROR interrupt status bit is set when a V_{BAT} (UV_VBAT = 1), V_{CC} (UV_VCC = 1) or V_{IO} (UV_VIO = 1) undervoltage is detected. It is reset after the flag (or flags) that triggered the interrupt has been reset and the Interrupt Status register has been read successfully. Resetting UV_ERROR triggers a falling edge on INTN to indicate to the host that the undervoltage condition is no longer present.

CLAMP_ERROR: A CLAMP_ERROR interrupt indicates that an input channel has become clamped or a collision has occurred on the TRXDO/1 interface.

The CLAMP_ERROR interrupt status bit is set when clamping is detected on TRXD (CLAMP_TRXD = 1), on TXEN (CLAMP_TXEN = 1) or on a branch (CLAMP_BRx = 1) or if a collision is detected on TRXD0/TRXD1 (COLL_TRXD = 1). It is reset after the flag (or flags) that triggered the interrupt has been reset and the Interrupt Status register has been read successfully. Resetting CLAMP_ERROR triggers a falling edge on INTN to indicate to the host that the clamp or collision error has been corrected.

SPI_ERROR: An SPI_ERROR interrupt indicates that an error has occurred during SPI communications.

The SPI_ERROR interrupt status bit is set if the number of SCLK cycles generated during a LOW phase on SCSN does not equal 16. It is reset after a successful read operation on the Interrupt Status register.

HC_ERROR: A HC_ERROR interrupt indicates that an invalid host command has been received.

The HC_ERROR interrupt status bit is set when the host requests an illegal mode transition (as defined in the Section 6.8.1 and Section 6.9.1). It is reset after a successful read operation on the Interrupt Status register.

TEMP_ERROR: A TEMP_ERROR interrupt signals the presence of an overtemperature condition.

The TEMP_ERROR interrupt status bit is set when the temperature warning level (TEMP_WARN = 1) or temperature high level (TEMP_HIGH = 1) is exceeded. It is reset after the flag (or flags) that triggered the interrupt has been reset and the Interrupt Status register has been read successfully. Resetting TEMP_ERROR triggers a falling edge on INTN to indicate to the host that the overtemperature condition is no longer present.

6.10.2.4 General Status register

The read-only General Status register contains status information not included in the Interrupt status register.

Table 10. General status register

Bit	Symbol	Description
11	WU_LOCAL	local wake-up on pin LWU:
		0: no wake-up detected
		1: wake-up detected
10	WU_TRXD	wake-up via TRXD0/TRXD1
		0: no wake-up detected
		1: wake-up detected
9	BGE_FB	BGE status feedback:
		0: if BGE is LOW
		1: if BGE is HIGH
8	UV_VBAT	V_{BAT} undervoltage
		0: no undervoltage detected
		1: undervoltage detected
7	UV_VCC	V_{CC} undervoltage
		0: no undervoltage detected
		1: undervoltage detected
6	UV_VIO	V_{IO} undervoltage
		0: no undervoltage detected
		1: undervoltage detected
5	TEMP_WARN	temperature warning level
		0: not exceeded
		1: exceeded
4	TEMP_HIGH	temperature high level
		0: not exceeded
		1: exceeded
3	CLAMP_TRXD	clamping detection on TRXD:
		0: not detected
		1: detected
2	CLAMP_TXEN	clamping detection on TXEN:
		0: not detected
		1: detected
1	COLL_TRXD	collision detection on TRXDO and TRXD1:
		0: not detected
		1:detected
0	PARITY	parity bit - odd parity (including parity bit)

WU_LOCAL:
WU_LOCAL is set when a local wake-up event is detected. A WU interrupt is generated.

WU_LOCAL is reset after the General Status register has been read successfully or when the TJA1085 switches from AS_Normal to AS_Standby or AS_Sleep. This ensures that a new wake-up event will be detected.

WU_TRXD:
WU_TRXD is set when a wake-up event is detected on the TRXD0/1 interface. A WU interrupt is generated.

WU_TRXD is reset after the General Status register has been read successfully or when the TJA1085 switches from AS_Normal to AS_Standby or AS_Sleep. This ensures that a new wake-up event will be detected.

BGE_FB:
Bit BGE_FB provides information about the voltage level on pin BGE.

BGE_FB is set when the voltage on BGE is HIGH and reset when the voltage on BGE is LOW.

UV_VBAT:
UV_VBAT is set when a V_{BAT} undervoltage is detected, generating a UV_ERROR interrupt.

If bit latching is enabled (BIT_LATCHING = 1), UV_BAT will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set if $V_{BAT} < V_{uvd(VBAT)}$ for longer than $t_{det(uv)(VBAT)}$ and reset if $V_{BAT} > V_{uvr(VBAT)}$ for longer than $t_{rec(uv)(VBAT)}$). If bit latching is not enabled, UV_BAT will reflect the 'live' situation at all times.

UV_VCC:
UV_VCC is set when a V_{CC} undervoltage is detected, generating a UV_ERROR interrupt.

If bit latching is enabled (BIT_LATCHING = 1), UV_VCC will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set if $V_{CC} < V_{uvd(VCC)}$ for longer than $t_{to(uvd)(VCC)}$ and reset if $V_{CC} > V_{uvr(VCC)}$ for longer than $t_{to(uvr)(VCC)}$). If bit latching is not enabled, UV_VCC will reflect the 'live' situation at all times.

UV_VIO:
UV_VIO is set when a V_{IO} undervoltage is detected, generating a UV_ERROR interrupt.

If bit latching is enabled (BIT_LATCHING = 1), UV_VIO will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set if $V_{IO} < V_{uvd(VIO)}$ for longer than $t_{to(uvd)(VIO)}$ and reset if $V_{IO} > V_{uvr(VIO)}$ for longer than $t_{to(uvr)(VIO)}$). If bit latching is not enabled, UV_VIO will reflect the 'live' situation at all times.

When a V_{IO} undervoltage is active, the digital inputs are disabled and the TJA1085 is unable to accept Host commands. If the V_{IO} undervoltage persists for longer than $t_{to(uvd)(VIO)}$, the APM flag is set and the TJA1085 switches from Host control to Autonomous control.

TEMP_WARN:
TEMP_WARN is set when the junction temperature rises above the temperature warning level, generating a TEMP_ERROR interrupt.

If bit latching is enabled (BIT_LATCHING = 1), TEMP_WARN will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set when $T_j > T_{j(warn)}$ and reset when $T_j < T_{j(warn)}$ with no activity on the bus or on the CC and TRXD0/1 interfaces). If bit latching is not enabled, TEMP_WARN will reflect the 'live' situation at all times.

TEMP_HIGH:
TEMP_HIGH is set when the junction temperature rises above the temperature high level. The output driver on the TRXD0/1 interface is disabled along with the branch transmitters (all branches switch to Branch_Disabled). A TEMP_ERROR interrupt is generated.

If bit latching is enabled (BIT_LATCHING = 1), TEMP_HIGH will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set when $T_j > T_{j(high)}$ and reset when $T_j < T_{j(high)}$ with no activity on the bus or on the CC and TRXD0/1 interfaces). If bit latching is not enabled, TEMP_HIGH will reflect the 'live' situation at all times.

CLAMP_TRXD:
CLAMP_TRXD is set when the TRXD0/1 interface is configured as an input and TRXD0 or TRXD1 is clamped LOW for longer than $t_{detCL(TRXD)}$. The output driver on the TRXD0/1 interface is disabled and data on the inputs is ignored. A CLAMP_ERROR interrupt is generated.

If bit latching is enabled, CLAMP_TRXD will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set when TRXD0 or TRXD1 clamped LOW and reset when TRXD0 and TRXD1 are HIGH). If bit latching is not enabled, CLAMP_TRXD will reflect the 'live' situation at all times.

CLAMP_TXEN:
CLAMP_TXEN is set when the TXEN is clamped LOW for longer than $t_{detCL(TXEN)}$. Data on TXD/TXEN is ignored and a CLAMP_ERROR interrupt is generated.

If bit latching is enabled, CLAMP_TXEN will remain set until the General Status register has been read, after which it will reflect the current 'live' situation (set when TXEN clamped LOW and reset when TXEN is HIGH). If bit latching is not enabled, CLAMP_TXEN will reflect the 'live' situation at all times.

COLL_TRXD:
COLL_TRXD is set when a collision is detected on the TRXD0/1 interface (TRXD0 and TRXD1 LOW for longer than $t_{det(col)(TRXD)}$). A CLAMP_ERROR interrupt is generated.

COLL_TRXD is reset once the General Status register has been read.

6.10.2.5 Branch X status registers

There is a dedicated read-only status register for each branch, i.e. there are four Branch X status registers in total. Each register contains relevant status information of a branch.

Table 11. Branch X status register

Bit	Symbol	Description
11-9	STATE_BRx	state of active branch:
		000: Branch_Normal mode
		001: Branch_Disabled mode
		010: Branch_LowPower mode
		011: Branch_TxOnly_2 mode
		100: Branch_FailSilent mode
		101: Branch_TxOnly_1 mode
8	WU_BRx	wake-up status
		0: no wake-up detected
		1: wake-up detected
7	reserved	always 0
6	TxE_BRx	transmit error on branch
		0: not detected
		1: detected
5	reserved	always 0
4	CLAMP_BRx	clamp detection on branch
		0: not detected
		1: detected
3	reserved	always 0
2	reserved	always 1
1	reserved	always 0
0	PARITY	parity bit - odd parity (including parity bit)

STATE_BRx:
Bits STATE_BRx indicate the current branch operating mode.

WU_BRx:
WU_BRx is set when a remote wake-up event is detected on a branch. A WU interrupt is generated along with an EVENT_BRx interrupt to indicate the branch where the wake-up pattern or dedicated data frame was detected.

WU_BRx is reset after the Branch Status register has been read successfully or when the TJA1085 switches from AS_Normal to AS_Standby or AS_Sleep. This ensures that a new wake-up event will be detected.

TxE_BRx:
TxE_BRx is set when a transmit error is detected on a branch, generating an EVENT_BRx interrupt. A transmit error is detected when there is a mismatch between the transmitted and received signals.

If bit latching is enabled (BIT_LATCHING = 1), TxE_BRx will remain set until the register has been read, after which it is reset if no mismatch is found between transmitted and received signals or the branch leaves Branch_Normal. If bit latching is not enabled, TxE_BRx is reset if no mismatch is found in a data frame or the branch leaves Branch_Normal.

CLAMP_BRx:
CLAMP_BRx is set when a branch is clamped for longer than $t_{detCL(bus)}$, generating a CLAMP_ERROR interrupt along with an EVENT_BRx interrupt to indicate the branch.

If bit latching is enabled (BIT_LATCHING = 1), CLAMP_BRx will remain set until the register has been read, after which it is reset when idle is detected on the branch. If bit latching is not enabled, CLAMP_BRx is reset when idle is detected on the branch.

7. Limiting values

Table 12. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are referenced to GND.

Symbol	Parameter	Conditions		Min	Max	Unit
V_{BAT}	battery supply voltage		[1]	–0.3	+48	V
		during load dump (400 ms max.)		–0.3	+60	V
I_{INH}	current on pin INH	AS_Normal, AS_Standby or AS_Reset		–1	0	mA
V_x	voltage on pin x[1]	on pins V_{CC}, V_{BUF}, V_{IO}, TRXD0, TRXD1, BGE, TXD, TXEN, RSTN, INTN, SCSN, SCLK, SDI, SDO		–0.3	+5.5	V
		on pins INH, LWU		–0.3	V_{BAT} + 0.3	V
		on pin RXD		–0.3	min(V_{IO} + 0.3, 5.5)	V
		on any BM/BP pin with respect to other BP/BM pins and GND		–60	+60	V
$I_{O(LWU)}$	output current on pin LWU			–15	-	mA
V_{trt}	transient voltage	on pins LWU, V_{BAT}, BP and BM	[2]	–100	-	V
			[3]	-	75	V
			[4]	–150	-	V
			[5]	-	100	V
T_{amb}	ambient temperature			–40	+125	°C
T_{vj}	virtual junction temperature		[6]	–40	+150	°C
T_{stg}	storage temperature			–55	+150	°C
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (150 pF, 330 Ω)	[7]			
		on pins BP and BM to GND		–6.0	+6.0	kV
		on pin LWU to GND	[8]	–6.0	+6.0	kV
		on pin V_{BAT} to GND	[9]	–6.0	+6.0	kV
		Human Body Model (HBM); 100 pF, 1.5 kΩ	[10]			
		on pins BP and BM to GND		–8.0	+8.0	kV
		on pins LWU and V_{BAT} to GND	[11]	–6.0	+6.0	kV
		on any other pin		–4.0	+4.0	kV
		Machine Model (MM); 200 pF, 0.75 μH, 10 Ω	[12]			
		on any pin		–200	+200	V
		Charged Device Model (CDM); field Induced charge; 4 pF	[13]			
		on any pin		–1000	+1000	V

[1] The device can sustain voltages up to the specified values over the product lifetime, provided applied voltages (including transients) never exceed these values.

[2] According to ISO7637, test pulse 1, class C; verified by an external test house.

[3] According to ISO7637, test pulse 2a, class C; verified by an external test house.

[4] According to ISO7637, test pulse 3a, class C; verified by an external test house.

[5] According to ISO7637, test pulse 3b, class C; verified by an external test house.

[6] In accordance with IEC 60747-1. An alternative definition of T_{vj} is: $T_{vj} = T_{amb} + P \times R_{th(j-a)}$, where $R_{th(j-a)}$ is a fixed value used in the calculation of T_{vj}. The rating for T_{vj} limits the allowable combinations of power dissipation (P) and ambient temperature (T_{amb}).

[7] According to IEC TS 62228 (2007), Section 4.3; DIN EN 61000-4-2; verified by an external test house. The test result is equal to or better than ±6 kV (unaided).

[8] With 3.3 kΩ in series.

[9] With 100 nF from V_{BAT} to GND.

[10] According to AEC-Q100-002.

[11] Guaranteed only when all n.c. pins are connected to GND.

[12] According to AEC-Q100-003.

[13] According to AEC-Q100-011 Rev-C1. The classification level is C6.

8. Thermal characteristics

Table 13. Thermal characteristics

Symbol	Parameter		Conditions	Typ	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	[1]	in free air	24	K/W
$R_{th(j-c)}$	thermal resistance from junction to case		in free air	2.5	K/W

[1] TJA1085 mounted on a JEDEC 2s2p board with 36 vias between layer 1 and layer 2; via diameter: 0.5 mm, wall thickness: 18 μm.

9. Static characteristics

Table 14. Static characteristics

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Power-on reset for V_{DIG}						
$V_{th(det)POR}$	power-on reset detection threshold voltage	of internal digital circuitry	3	-	3.4	V
$V_{th(rec)POR}$	power-on reset recovery threshold voltage	of internal digital circuitry	3.1	-	3.5	V
$V_{hys(POR)}$	power-on reset hysteresis voltage	of internal digital circuitry	100		500	mV
$\Delta V_{(VCC-VDIG)}$	voltage difference between V_{CC} and V_{DIG}	V_{CC} = 4.45 V; V_{BAT} = V_{BUF} = 0 V	-	-	1.0	V
$\Delta V_{(VBAT-VDIG)}$	voltage difference between V_{BAT} and V_{DIG}	V_{BAT} = 4.45 V; V_{CC} = V_{BUF} = 0 V	-	-	1.0	V
$\Delta V_{(VBUF-VDIG)}$	voltage difference between V_{BUF} and V_{DIG}	V_{BUF} = 4.45 V; V_{CC} = V_{BAT} = 0 V	-	-	1.0	V
Supply: pin V_{BAT}						
V_{BAT}	battery supply voltage	operating range	4.75	-	60	V
I_{BAT}	battery supply current	AS_Normal; no load on INH	-	0.1	1	mA
		AS_Standby; no load on INH; wake-up enabled on all branches	-	50	100	µA
		AS_Sleep; wake-up enabled on all branches	-	50	100	µA
		AS_Sleep; wake-up enabled on all branches; $T_{vj} \leq 85$ °C	-	50	90	µA
		AS_Sleep; wake-up disabled on all branches	-	25	55	µA
		AS_Sleep; wake-up disabled on all branches; $T_{vj} \leq 85$ °C	-	25	45	µA
V_{uvd}	undervoltage detection voltage		4.45	-	4.715	V
V_{uvr}	undervoltage recovery voltage		4.475	-	4.74	V
V_{uvhys}	undervoltage hysteresis voltage		25	-	290	mV
Supply: pins V_{CC1} and V_{CC2} (connected on the PCB)						
V_{CC}	supply voltage	operating range	4.75	-	5.25	V

Table 14. Static characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
I_{CC}	supply current	AS_Normal; V_{TXEN} = 0 V; V_{BGE} = V_{IO}; R_{bus} = 45 Ω; all branches in Branch_Normal	[1]	-	180	210	mA
		AS_Normal; V_{TXEN} = V_{IO}; V_{BGE} = 0 V; R_{bus} = 45 Ω; all branches in Branch_Normal and/or Branch_Disabled	[1]	-	-	80	mA
		AS_Standby	[1][2]	-	4	35	µA
		AS_Standby; T_{vj} ≤ 85 °C	[1][2]	-	4	15	µA
		AS_Sleep, AS_Reset	[1][2]	-	0	30	µA
		AS_Sleep, AS_Reset; T_{vj} ≤ 85 °C	[1][2]	-	0	10	µA
V_{uvd}	undervoltage detection voltage			4.45	-	4.715	V
V_{uvr}	undervoltage recovery voltage			4.475	-	4.74	V
V_{uvhys}	undervoltage hysteresis voltage			25	-	290	mV
Supply: pins V_{BUF1} and V_{BUF2} (connected on the PCB)							
V_{BUF}	supply voltage on pin V_{BUF}	5.5 V ≤ V_{BAT} ≤ 60 V; V_{CC} ≤ $V_{uvd(VCC)}$		4.5	-	5.25	V
		4.5 V ≤ V_{BAT} ≤ 5.5 V; V_{CC} ≤ $V_{uvd(VCC)}$		3.5	-	5.25	V
$\Delta V_{(VCC-VBUF)}$	voltage difference between V_{CC} and V_{BUF}	V_{CC} ≥ $V_{uvr(VCC)}$		0	-	0.25	V
$I_{ch(VBAT-VBUF)}$	charge current from V_{BAT} to V_{BUF}	5.5 V ≤ V_{BAT} ≤ 60 V; V_{CC} ≤ $V_{uvd(VCC)}$; 0 V ≤ V_{BUF} ≤ 4 V		−200	−100	−30	µA
V_{uvd}	undervoltage detection voltage			4.2	-	4.474	V
V_{uvr}	undervoltage recovery voltage			4.225	-	4.499	V
V_{uvhys}	undervoltage hysteresis voltage			25	-	299	mV
Supply: pin V_{IO}							
V_{IO}	supply voltage on pin V_{IO}	operating range		2.8	-	5.25	V
I_{IO}	supply current on pin V_{IO}	AS_Normal; V_{TXD} = V_{IO}		-	-	1000	µA
		AS_Standby; AS_Sleep; AS_PowerOff; V_{SCSN} = V_{TXEN} = V_{RSTN} = V_{VIO}		-	2	7	µA
I_r	reverse current	from digital input pin to V_{IO}; AS_PowerOff; V_{TXEN} = V_{TXD} = V_{BGE} = V_{SCSN} = V_{SCLK} = V_{SDI} = V_{RSTN} = 5.25 V; V_{CC} = V_{IO} = 0 V		−5	-	+5	µA

Table 14. Static characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{uvd}	undervoltage detection voltage			2.55	-	2.765	V
V_{uvr}	undervoltage recovery voltage			2.575	-	2.79	V
V_{uvhys}	undervoltage hysteresis voltage			25	-	240	mV
Pin TXEN							
V_{IH}	HIGH-level input voltage	AS_Normal		$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage	AS_Normal		−0.3	-	$0.3V_{IO}$	V
I_{IH}	HIGH-level input current	$V_{TXEN} = V_{IO}$		−2	-	+2	µA
I_{IL}	LOW-level input current	$V_{TXEN} = 0.3V_{IO}$		−300	-	−50	µA
Pin TXD							
V_{IH}	HIGH-level input voltage	AS_Normal		$0.6V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage	AS_Normal		−0.3	-	$0.4V_{IO}$	V
R_{pd}	pull-down resistance	to GND		50	150	400	kΩ
C_i	input capacitance	with respect to all other pins at ground; V_{TXD} = 100 mV; f = 5 MHz	[3]	-	-	10	pF
Pin BGE							
V_{IH}	HIGH-level input voltage	AS_Normal		$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage	AS_Normal		−0.3	-	$0.3V_{IO}$	V
R_{pd}	pull-down resistance	to GND		50	150	400	kΩ
Pin RXD							
I_{OH}	HIGH-level output current	$V_{RXD} = V_{IO} - 0.4$ V		−15	-	−1	mA
I_{OL}	LOW-level output current	V_{RXD} = 0.4 V		1	-	15	mA
V_{OH}	HIGH-level output voltage	$I_{OH(RXD)}$ = −1 mA		V_{IO} − 0.4	-	V_{IO}	V
V_{OL}	LOW-level output voltage	$I_{OL(RXD)}$ = 1 mA		-	-	0.4	V
V_O	output voltage	when undervoltage on V_{IO}; $V_{CC} \geq$ 4.75 V; R_L = 100 kΩ to GND		-	-	500	mV
		$V_{CC} = V_{BAT} = V_{BUF}$ = 0 V; R_L = 100 kΩ to V_{IO}		V_{IO} − 500	-	V_{IO}	mV
Pin RSTN							
V_{IH}	HIGH-level input voltage			$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage			−0.3	-	$0.3V_{IO}$	V
I_{IH}	HIGH-level input current	$V_{RSTN} = V_{IO}$		−1	-	+1	µA
I_{IL}	LOW-level input current	$V_{RSTN} = 0.3V_{IO}$		−300	-	−30	µA
Pins TRXD0 and TRXD1							
V_{IH}	HIGH-level input voltage			$0.7V_{BUF}$	-	5.5	V
V_{IL}	LOW-level input voltage			−0.3	-	$0.3V_{BUF}$	V
V_{OL}	LOW-level output voltage	R_{pu} = 200 Ω		−0.3	-	+0.8	V

Table 14. Static characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
C_i	input capacitance	with respect to all other pins at GND; V_{TXD} = 100 mV; f = 5 MHz	[3]	-	-	15	pF
R_{pu}	pull-up resistance	to V_{BUF}		2.5	5	10	kΩ
Pins BP and BM							
$V_{IH(dif)}$	differential HIGH-level input voltage	AS_Normal; −10 V ≤ V_{cm} ≤ +15 V	[4]	150	-	300	mV
$V_{IL(dif)}$	differential LOW-level input voltage	AS_Normal; −10 V ≤ V_{cm} ≤ +15 V	[4]	−300	-	−150	mV
		AS_Standby; AS_Sleep; −10 V ≤ V_{cm} ≤ +15 V	[4]	−400	-	−125	mV
$\Delta V_{i(dif)(H-L)}$	differential input voltage difference between HIGH-level and LOW-level	V_{cm} = 2.5 V; AS_Normal	[4]	−30	-	+30	mV
$V_{OH(dif)}$	differential HIGH-level output voltage	4.75 V ≤ V_{BUF} ≤ 5.25 V		900	-	2000	mV
		4.45 V ≤ V_{BUF} ≤ 5.25 V		700	-	2000	mV
$V_{OL(dif)}$	differential LOW-level output voltage	4.75 V ≤ V_{BUF} ≤ 5.25 V		−2000	-	−900	mV
		4.45 V ≤ V_{BUF} ≤ 5.25 V		−2000	-	−700	mV
$V_{o(idle)(BP)}$	idle output voltage on pin BP	Branch_Normal		0.4V_{BUF}	-	0.6V_{BUF}	V
		Branch_LowPower		−0.1	-	+0.1	V
$V_{o(idle)(BM)}$	idle output voltage on pin BM	Branch_Normal		0.4V_{BUF}	-	0.6V_{BUF}	V
		Branch_LowPower		−0.1	-	+0.1	V
$I_{o(idle)BP}$	idle output current on pin BP	−60 V ≤ V_{BP} ≤ +60 V; no bus load		−7.5	-	+7.5	mA
$I_{o(idle)BM}$	idle output current on pin BM	−60 V ≤ V_{BM} ≤ +60 V; no bus load		−7.5	-	+7.5	mA
$V_{o(idle)(dif)}$	differential idle output voltage			−25	0	+25	mV
$\lvert V_{i(dif)det(act)} \rvert$	activity detection differential input voltage (absolute value)	AS_Normal; −10 V ≤ V_{cm} ≤ +15 V	[4]	150	-	300	mV
$V_{cm(bus)(DATA\_0)}$	DATA_0 bus common-mode voltage	Branch_Transmit		0.4V_{BUF}	-	0.65 × V_{BUF}	V
$V_{cm(bus)(DATA\_1)}$	DATA_1 bus common-mode voltage	Branch_Transmit		0.4V_{BUF}	-	0.65 × V_{BUF}	V
R_i	input resistance	R_{bus} = ∞ Ω		10	20	40	kΩ
$R_{i(dif)(BP-BM)}$	differential input resistance between pin BP and pin BM	R_{bus} = ∞ Ω		20	40	80	kΩ
$Z_{o(eq)TX}$	transmitter equivalent output impedance	C_{bus} = 100 pF; R_{bus} = 40 Ω or 100 Ω	[5]	10	-	600	Ω
$C_{i(BP)}$	input capacitance on pin BP	with respect to all other pins at GND; V_{BP} = 100 mV; f = 5 MHz	[3]	-	-	15	pF
$C_{i(BM)}$	input capacitance on pin BM	with respect to all other pins at GND; V_{BM} = 100 mV; f = 5 MHz	[3]	-	-	15	pF
$C_{i(dif)(BP-BM)}$	differential input capacitance between pin BP and pin BM	V_{BP} = 100 mV; V_{BM} = 100 mV; f = 5 MHz	[3]	-	-	5	pF

Table 14. Static characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$I_{LI(BP)}$	input leakage current on pin BP	AS_PowerOff; V_{BP} = V_{BM}; 0 V ≤ V_{BP} ≤ 5 V		−5	0	+5	µA
		loss of ground; V_{BP} = V_{BM} = 0 V; all other pins connected to 16 V via 0 Ω	[3]	−1600	-	+1600	µA
$I_{LI(BM)}$	input leakage current on pin BM	AS_PowerOff; V_{BP} = V_{BM}; 0 V ≤ V_{BM} ≤ 5 V		−5	0	+5	µA
		loss of ground; V_{BP} = V_{BM} = 0 V; all other pins connected to 16 V via 0 Ω	[3]	−1600	-	+1600	µA
$\lvert I_{O(sc)} \rvert$	short-circuit output current (absolute value)	on pin BP; −5 V ≤ V_{BP} ≤ +60 V; R_{sc} ≤ 1 Ω; t_{sc} ≥ 1500 µs	[6][8]	-	-	72	mA
		on pin BP; −5 V ≤ V_{BP} ≤ +27 V; R_{sc} ≤ 1 Ω; t_{sc} ≥ 1500 µs	[6][8]	-	-	60	mA
		on pin BM; −5 V ≤ V_{BM} ≤ +60 V; R_{sc} ≤ 1 Ω; t_{sc} ≥ 1500 µs	[6][8]	-	-	72	mA
		on pin BM; −5 V ≤ V_{BM} ≤ +27 V; R_{sc} ≤ 1 Ω; t_{sc} ≥ 1500 µs	[6][8]	-	-	60	mA
		on pins BP and BM; V_{BP} = V_{BM}; R_{sc} ≤ 1 Ω; t_{sc} ≥ 1500 µs	[7][8]	-	-	60	mA
Pin INH							
V_{OH}	HIGH-level output voltage	I_{INH} = −0.2 mA: AS_Normal; AS_Standby; AS_Reset		V_{BAT} − 0.8	-	V_{BAT}	V
I_L	leakage current	AS_Sleep; AS_PowerOff		−3	-	+3	µA
$I_{O(sc)}$	short-circuit output current	V_{INH} = 0 V; AS_Normal; AS_Standby; AS_Reset		−7	-	−1	mA
Pin LWU							
$V_{th(wake)LWU}$	wake-up threshold voltage on pin LWU	AS_Sleep; AS_Standby		2	-	3.75	V
$V_{hys(wake)LWU}$	wake-up hysteresis voltage on pin LWU			0.3	-	1.2	V
I_{IL}	LOW-level input current	V_{LWU} = 2 V for t > $t_{det(wake)(LWU)}$		3	-	11	µA
		V_{LWU} = 0 V		−2	-	−0.3	µA
I_{IH}	HIGH-level input current	V_{LWU} = 3.75 V for t > $t_{det(wake)(LWU)}$; 4.75 V ≤ V_{BAT} ≤ +60 V		−11	-	−3	µA
		V_{LWU} = V_{BAT}		0.2	-	1.2	µA
Pin SDO							
V_{OH}	HIGH-level output voltage	$I_{OH(SDO)}$ = −0.5 mA		V_{IO} − 0.4	-	V_{IO}	V
V_{OL}	LOW-level output voltage	$I_{OL(SDO)}$ = 0.5 mA		-	-	0.4	V
I_{OH}	HIGH-level output current	V_{SDO} = V_{IO} − 0.4 V		−8	−2	−0.5	mA
I_{OL}	LOW-level output current	V_{SDO} = 0.4 V		0.5	2	8	mA
I_L	leakage current	SCSN HIGH		−5	-	+5	µA

Table 14. Static characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to +150 °C; C_{bus} = 100 pF; R_{bus} = 40 Ω to 55 Ω; C_{RXD} = 15 pF and C_{TRXD0} = C_{TRXD1} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_O	output voltage	when undervoltage on V_{IO}; $V_{CC} \geq 4.75$ V; R_L = 100 kΩ to GND	-	-	500	mV
		V_{CC} = V_{BAT} = V_{BUF} = 0 V; R_L = 100 kΩ to GND	-	-	500	mV
Pin SDI						
V_{IH}	HIGH-level input voltage		$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage		−0.3	-	$0.3V_{IO}$	V
R_{pd}	pull-down resistance	to GND	50	150	400	kΩ
Pin SCSN						
V_{IH}	HIGH-level input voltage		$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage		−0.3	-	$0.3V_{IO}$	V
I_{IH}	HIGH-level input current	V_{SCSN} = V_{IO}	−1	-	+1	µA
I_{IL}	LOW-level input current	V_{SCSN} = $0.3V_{IO}$	−15	-	−3	µA
Pin SCLK						
V_{IH}	HIGH-level input voltage		$0.7V_{IO}$	-	5.5	V
V_{IL}	LOW-level input voltage		−0.3	-	$0.3V_{IO}$	V
R_{pd}	pull-down resistance	to GND	50	150	400	kΩ
Pin INTN						
V_{OL}	LOW-level output voltage	$I_{OL(INTN)}$ = 0.5 mA	-	-	0.4	V
V_O	output voltage	when undervoltage on V_{IO}; $V_{CC} \geq 4.75$ V; R_L = 100 kΩ to GND	-	-	500	mV
		V_{CC} = V_{BAT} = V_{BUF} = 0 V; R_L = 100 kΩ to GND	-	-	500	mV
Temperature protection						
$T_{j(warn)}$	warning junction temperature		155	-	190	°C
$T_{j(high)}$	high junction temperature		165	-	200	°C
$\Delta T_{j(high-warn)}$	difference between high and warning junction temperature		10	-	45	°C

[1] Specified current is the sum of currents I_{CC1} and I_{CC2}.

[2] These values are guaranteed under the condition that the internal digital block is supplied from V_{BAT}.

[3] Guaranteed by design.

[4] V_{cm} is the BP/BM common mode voltage.

[5] $Z_{o(eq)(TX)} = 50\ \Omega \times (V_{bus(100)} - V_{bus(40)})/(2.5 \times V_{bus(40)} - V_{bus(100)})$ where:
- $V_{bus(100)}$ is the differential output voltage on a load of 100 Ω and 100 pF in parallel
- $V_{bus(40)}$ is the differential output voltage on a load of 40 Ω and 100 pF in parallel when driving a DATA_1.

[6] R_{sc} is the short-circuit resistance; voltage difference between bus pins BP and BM is 60 V max.

[7] R_{sc} is the short-circuit resistance between BP and BM.

[8] t_{sc} is the minimum duration of the short-circuit

10. Dynamic characteristics

Table 15. Dynamic characteristics

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to + 150 °C; R_{bus} = 40 Ω, C_{bus} = 100 pF; C_{RXD} = 15 pF; C_{TRXD0} = C_{TRXD1} = 50 pF and C_{SDO} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Undervoltage detection						
$t_{det(uv)(VBAT)}$	undervoltage detection time on pin V_{BAT}	V_{BAT} = 4.35 V	5	-	150	µs
$t_{rec(uv)(VBAT)}$	undervoltage recovery time on pin V_{BAT}	V_{BAT} = 4.85 V	5	-	150	µs
$t_{det(uv)(VCC)}$	undervoltage detection time on pin V_{CC}	V_{CC} = 4.35 V	5	-	100	µs
$t_{rec(uv)(VCC)}$	undervoltage recovery time on pin V_{CC}	V_{CC} = 4.85 V	5	-	100	µs
$t_{det(uv)(VBUF)}$	undervoltage detection time on pin V_{BUF}	V_{BUF} = 4.10 V	5	-	100	µs
$t_{rec(uv)(VBUF)}$	undervoltage recovery time on pin V_{BUF}	V_{BUF} = 4.6 V	5	-	100	µs
$t_{det(uv)(VIO)}$	undervoltage detection time on pin V_{IO}	V_{IO} = 2.45 V	5	-	100	µs
$t_{rec(uv)(VIO)}$	undervoltage recovery time on pin V_{IO}	V_{IO} = 2.9 V	5	-	100	µs
$t_{to(uvd)(VCC)}$	undervoltage detection time-out time on pin V_{CC}		100	-	670	ms
$t_{to(uvd)(VIO)}$	undervoltage detection time-out time on pin V_{IO}		100	-	670	ms
$t_{to(uvr)(VCC)}$	undervoltage recovery time-out time on pin V_{CC}		1	-	5	ms
$t_{to(uvr)(VIO)}$	undervoltage recovery time-out time on pin V_{IO}		1	-	5	ms
SPI						
$t_{cy(clk)}$	clock cycle time		0.5	-	100	µs
$t_{SPILEAD}$	SPI enable lead time		250	-	-	ns
t_{SPILAG}	SPI enable lag time		250	-	-	ns
$t_{su(D)}$	data input set-up time		150	-	-	ns
$t_{h(D)}$	data input hold time		100	-	-	ns
$t_{d(SCLK-SDO)}$	delay time from SCLK to SDO		-	-	200	ns
$t_{WH(S)}$	chip select pulse width HIGH		10	-	-	µs
$t_{d(SCSNHL-SDOL)}$	SCSN falling edge to SDO LOW-level delay time		-	-	250	ns
$t_{d(SCSNLH-SDOZ)}$	SCSN rising edge to SDO three-state delay time		-	-	500	ns

Table 15. Dynamic characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to + 150 °C; R_{bus} = 40 Ω, C_{bus} = 100 pF; C_{RXD} = 15 pF; C_{TRXD0} = C_{TRXD1} = 50 pF and C_{SDO} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Transmit path							
$t_{d(TXD-bus)}$	delay time from TXD to bus	AS_Normal; see Figure 10	[1]				
		DATA_0		-	-	75	ns
		DATA_1		-	-	75	ns
$\Delta t_{d(TXD-bus)}$	delay time difference from TXD to bus	between DATA_0 and DATA_1; AS_Normal	[1] [2]	−5	-	+5	ns
$t_{d(TXD-TRXD)}$	delay time from TXD to TRXD	AS_Normal; see Figure 10	[1]				
		DATA_0		-	-	60	ns
		DATA_1		-	-	60	ns
$\Delta t_{d(TXD-TRXD)}$	delay time difference from TXD to TRXD	between DATA_0 and DATA_1; AS_Normal	[1]	−5	-	+5	ns
$t_{d(TRXD-bus)}$	delay time from TRXD to bus	AS_Normal; see Figure 12					
		DATA_0		-	-	75	ns
		DATA_1		-	-	75	ns
$\Delta t_{d(TRXD-bus)}$	delay time difference from TRXD to bus	between DATA_0 and DATA_1; AS_Normal	[2]	−5	-	+5	ns
$t_{d(TXEN-busact)}$	delay time from TXEN to bus active	AS_Normal; from idle to active		-	-	150	ns
$t_{d(TXEN-busidle)}$	delay time from TXEN to bus idle	AS_Normal; from active to idle		-	-	150	ns
$t_{d(TXEN-RXD)}$	delay time from TXEN to RXD			-	-	150	ns
$t_{d(TRXD-busact)}$	delay time from TRXD to bus active	$t_{det(act)(TRXD)} + t_{d(TRXD-bus)}$		-	-	275	ns
$t_{d(TRXD-busidle)}$	delay time from TRXD to bus idle	$t_{det(idle)(TRXD)} + t_{d(TRXD-bus)}$		-	-	275	ns
$t_{d(busact-TRXD)}$	delay time from bus active to TRXD	$t_{det(act)(bus)} + t_{d(bus-TRXD)}$		-	-	285	ns
$t_{d(busidle-TRXD)}$	delay time from bus idle to TRXD	$t_{det(idle)(bus)} + t_{d(bus-TRXD)}$		-	-	275	ns
$t_{d(TRXDact-RXD)}$	delay time from TRXD activity detection to RXD	$t_{det(act)(TRXD)} + t_{d(TRXD-RXD)}$		-	-	260	ns
$t_{d(busact-bus)}$	delay time from bus active to bus	from one branch to another, including activity detection time; $t_{det(act)(bus)} + t_{d(bus-bus)}$		-	-	310	ns
$t_{d(busidle-bus)}$	delay time from bus idle to bus	from one branch to another, including idle detection time; $t_{det(idle)(bus)} + t_{d(bus-bus)}$		-	-	300	ns
Receive path							
$t_{d(bus-TRXD)}$	delay time from bus to TRXD	AS_Normal; see Figure 11					
		DATA_0		-	-	75	ns
		DATA_1		-	-	75	ns
$\Delta t_{d(bus-TRXD)}$	delay time difference from bus to TRXD	between DATA_0 and DATA_1 AS_Normal; V_{cm} = 2.5 V R_{pu} = 200 Ω	[2] [3]	−5	-	+5	ns

Table 15. Dynamic characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to + 150 °C; R_{bus} = 40 Ω, C_{bus} = 100 pF; C_{RXD} = 15 pF; C_{TRXD0} = C_{TRXD1} = 50 pF and C_{SDO} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$t_{d(bus-RXD)}$	delay time from bus to RXD	AS_Normal; see Figure 11					
		DATA_0		-	-	75	ns
		DATA_1		-	-	75	ns
$\Delta t_{d(bus-RXD)}$	delay time difference from bus to RXD	between DATA_0 and DATA_1 AS_Normal; V_{cm} = 2.5 V	[2] [3]	−5	-	+5	ns
$t_{d(TRXD-RXD)}$	delay time from TRXD to RXD	AS_Normal; see Figure 12					
		DATA_0		-	-	60	ns
		DATA_1		-	-	60	ns
$\Delta t_{d(TRXD-RXD)}$	delay time difference from TRXD to RXD	between DATA_0 and DATA_1 AS_Normal		−5	-	+5	ns
$t_{d(TXD-RXD)}$	delay time from TXD to RXD	AS_Normal; see Figure 10	[1]				
		DATA_0		-	30	60	ns
		DATA_1		-	30	60	ns
$t_{d(bus-bus)}$	delay time from bus to bus	from one branch to another AS_Normal; see Figure 11					
		DATA_0		-	-	100	ns
		DATA_1		-	-	100	ns
$\Delta t_{d(bus-bus)}$	delay time difference from bus to bus	between DATA_0 and DATA_1 AS_Normal		−8	-	+8	ns
Bus slope							
$t_{r(dif)(bus)}$	bus differential rise time	DATA_0 to DATA_1; 20 % to 80 %		6	-	18.75	ns
		DATA_0 to idle; −300 mV to −30 mV		-	-	30	ns
$t_{f(dif)(bus)}$	bus differential fall time	DATA_1 to DATA_0; 20 % to 80 %		6	-	18.75	ns
		DATA_1 to idle; 300 mV to 30 mV		-	-	30	ns
		idle to DATA_0; −30 mV to −300 mV		-	-	30	ns
$\Delta t_{(r-f)(dif)}$	difference between differential rise and fall time	between DATA_0 and DATA_1		−3	-	+3	ns
Pin RXD							
t_r	rise time	20 % to 80 %		-	-	9	ns
t_f	fall time	80 % to 20 %		-	-	9	ns
$t_{(r+f)}$	sum of rise and fall time	20 % to 80 % and 80 % to 20 %		-	-	13	ns
$\Delta t_{(r-f)}$	difference between rise and fall time	20 % to 80 %		−5	-	+5	ns
Pin RSTN							
$t_{det(rst)}$	reset detection time			5	-	20	µs
Pin BGE							
$t_{d(BGE-busact)}$	delay time from BGE to bus active	activity detected on TXEN		-	-	100	ns
$t_{d(BGE-busidle)}$	delay time from BGE to bus idle	activity detected on TXEN		-	-	100	ns

Table 15. Dynamic characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to + 150 °C; R_{bus} = 40 Ω, C_{bus} = 100 pF; C_{RXD} = 15 pF; C_{TRXD0} = C_{TRXD1} = 50 pF and C_{SDO} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Activity detection							
$t_{det(act)(TXEN)}$	activity detection time on pin TXEN	AS_Normal; from idle to active		20	-	70	ns
$t_{det(idle)(TXEN)}$	idle detection time on pin TXEN	AS_Normal; from active to idle		20	-	70	ns
$\Delta t_{det(act-idle)}$	difference between active and idle detection time						
	on pin TXEN	AS_Normal		−25	-	+25	ns
	on pin TRXD	pins TRXD0 and TRXD1; AS_Normal		−50	-	+50	ns
	on bus	AS_Normal		−50	-	+50	ns
$t_{det(act)(TRXD)}$	activity detection time on pin TRXD	pins TRXD0 and TRXD1; AS_Normal; from idle to active		100	-	200	ns
$t_{det(idle)(TRXD)}$	idle detection time on pin TRXD	pins TRXD0 and TRXD1; AS_Normal; from active to idle		100	-	200	ns
$t_{det(act)(bus)}$	activity detection time on bus pins	AS_Normal; from idle to active		100	-	210	ns
$t_{det(idle)(bus)}$	idle detection time on bus pins	AS_Normal; from active to idle		100	-	200	ns
$t_{det(int)}$	interrupt detection time	from interrupt detection to falling edge on INTN		-	-	100	µs
$t_{INTNH(min)}$	minimum INTN HIGH time			10	-	40	µs
Wake-up detection							
$t_{det(wake)DATA\_0}$	DATA_0 wake-up detection time	$-10\ V \leq V_{cm} \leq +15\ V$	[3]	1	-	4	µs
$t_{det(wake)idle}$	idle wake-up detection time	$-10\ V \leq V_{cm} \leq +15\ V$	[3]	1	-	4	µs
$t_{det(wake)tot}$	total wake-up detection time	$-10\ V \leq V_{cm} \leq +15\ V$	[3]	50	-	115	µs
$t_{sup(int)wake}$	wake-up interruption suppression time	$-10\ V \leq V_{cm} \leq +15\ V$	[3]	130	-	1000	ns
$t_{d(bus)(wake-act)}$	bus delay time from wake-up to active			-	-	18	µs
$t_{det(wake)(LWU)}$	wake-up detection time on pin LWU			2.9	-	175	µs
$t_{det(wake)(TRXD)}$	wake-up detection time on pin TRXD	falling edge on TRXD_0 or TRXD_1		100	-	400	ns
$t_{d(LWUwake-INHH)}$	delay time from LWU wake-up to INH HIGH	falling edge on LWU to INH HIGH AS_Sleep; 5.5 V < V_{BAT} < 27 V $R_{L(INH-GND)}$ = 100 kΩ	[4]	2.9	-	100	µs
		falling edge on LWU to INH HIGH AS_Sleep; 27 V < V_{BAT} < 60 V $R_{L(INH-GND)}$ = 100 kΩ	[4]	-	-	175	µs
$t_{d(buswake-INHH)}$	delay time from bus wake-up to INH HIGH	AS_Sleep; V_{BAT} > 5.5 V $R_{L(INH-GND)}$ = 100 kΩ	[4]	-	-	55	µs
$t_{d(buswake-INTNL)}$	delay time from bus wake-up to INTN LOW	AS_Sleep; AS_Standby V_{BAT} > 5.5 V		-	-	10	µs
$t_{d(TRXDwake-INHH)}$	delay time from TRXD wake-up to INH HIGH	falling edge on TRXDx to INH HIGH AS_Sleep; $R_{L(INH-GND)}$ = 100 kΩ	[4]	-	-	55	µs

Table 15. Dynamic characteristics *...continued*

All parameters are guaranteed for V_{BAT} = 4.45 V to 60 V; V_{CC} = 4.45 V to 5.25 V; V_{BUF} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = −40 °C to + 150 °C; R_{bus} = 40 Ω, C_{bus} = 100 pF; C_{RXD} = 15 pF; C_{TRXD0} = C_{TRXD1} = 50 pF and C_{SDO} = 50 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Bus error diagnosis						
$t_{to(BFT)}$	BFT time-out time		80	-	180	ns
Clamp detection						
$t_{detCL(bus)}$	bus clamp detection time		650	-	2600	µs
$t_{detCL(TRXD)}$	TRXD clamp detection time		650	-	2600	µs
$t_{detCL(TXEN)}$	TXEN clamp detection time		650	-	2600	µs
$t_{det(col)(TRXD)}$	TRXD collision detection time		40	-	120	ns
Transition timing						
$t_{to\_stargotosleep}$	dStarGoToSleep time-out time		640	-	6400	ms
$t_{t(bnorm-bdis)}$	branch normal to branch disabled transition time	AS_Normal; after a host 'Branch_Disabled' command; rising edge on SCSN to transmitter deactivated	-	-	1	µs
$t_{t(bdis-bnorm)}$	branch disabled to branch normal transition time	AS_Normal; after a host 'Branch_Normal' command; rising edge on SCSN to transmitter activated	-	-	1	µs
$t_{t(bnorm-btx2)}$	branch normal to branch TxOnly2 transition time	AS_Normal; after a host 'Branch_TxOnly' command; rising edge on SCSN to deactivating receive function	-	-	1	µs
$t_{t(btx2-bnorm)}$	branch TxOnly2 to branch normal transition time	AS_Normal; after a host 'Branch_Normal' command; rising edge on SCSN to activating receive function	-	-	1	µs
$t_{t(moch)}$	mode change transition time	after host command AS_Sleep to AS_Standby rising edge on SCSN to rising edge on INH	-	-	25	µs

[1] Sum of rise and fall times on TXD (20 % to 80 % on V_{IO}) is 9 ns (max).

[2] Guaranteed for $V_{bus(dif)}$ = ±300 mV and $V_{bus(dif)}$ = ±150 mV; $V_{bus(dif)}$ is the differential bus voltage, V_{BP} - V_{BM}.

[3] V_{cm} is the BP/BM common mode voltage (V_{cm} = (V_{BP} + V_{BM})/2).

[4] Defined for V_{INH} = 2 V.

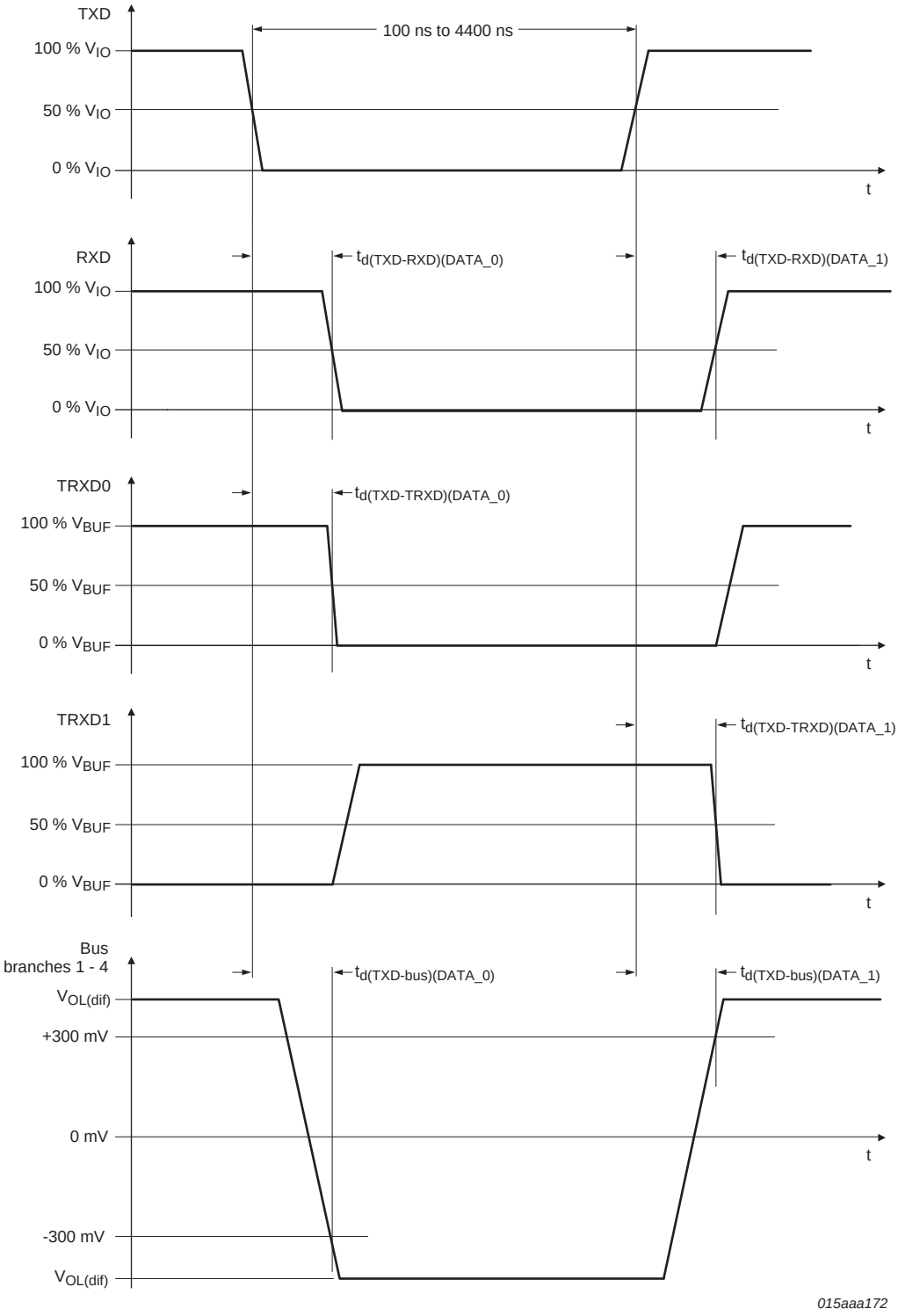
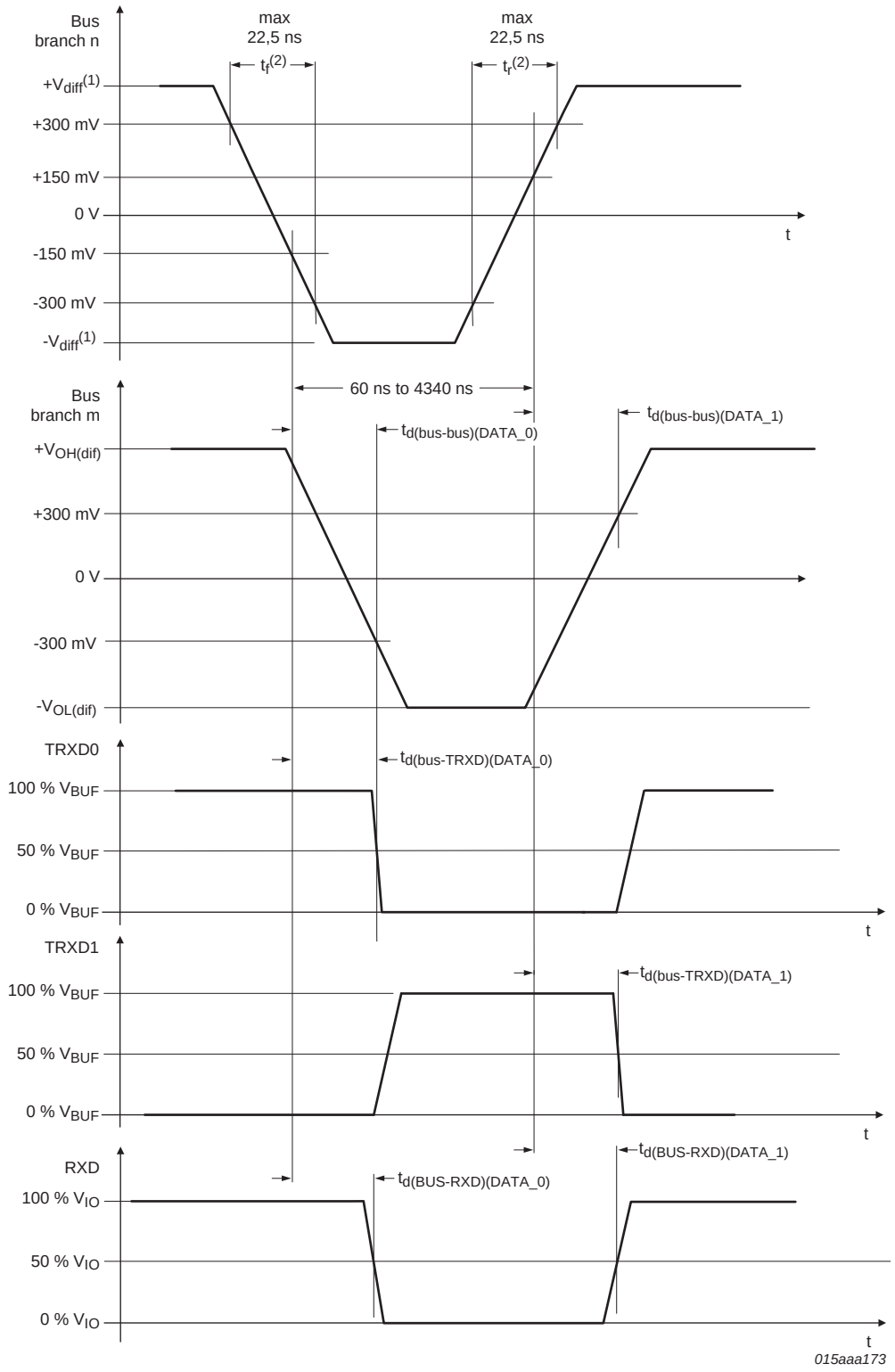


Fig 10. Timing diagram when the CC interface is the input channel



(1) V_{dif} = 400 mV to 3000 mV.

(2) t_r and t_f, defined between ±300 mV, are both 22.5 ns for bus amplitudes of 800 mV (max), and lower for higher bus amplitudes.

Fig 11. Timing diagram when one of the branches is the input channel

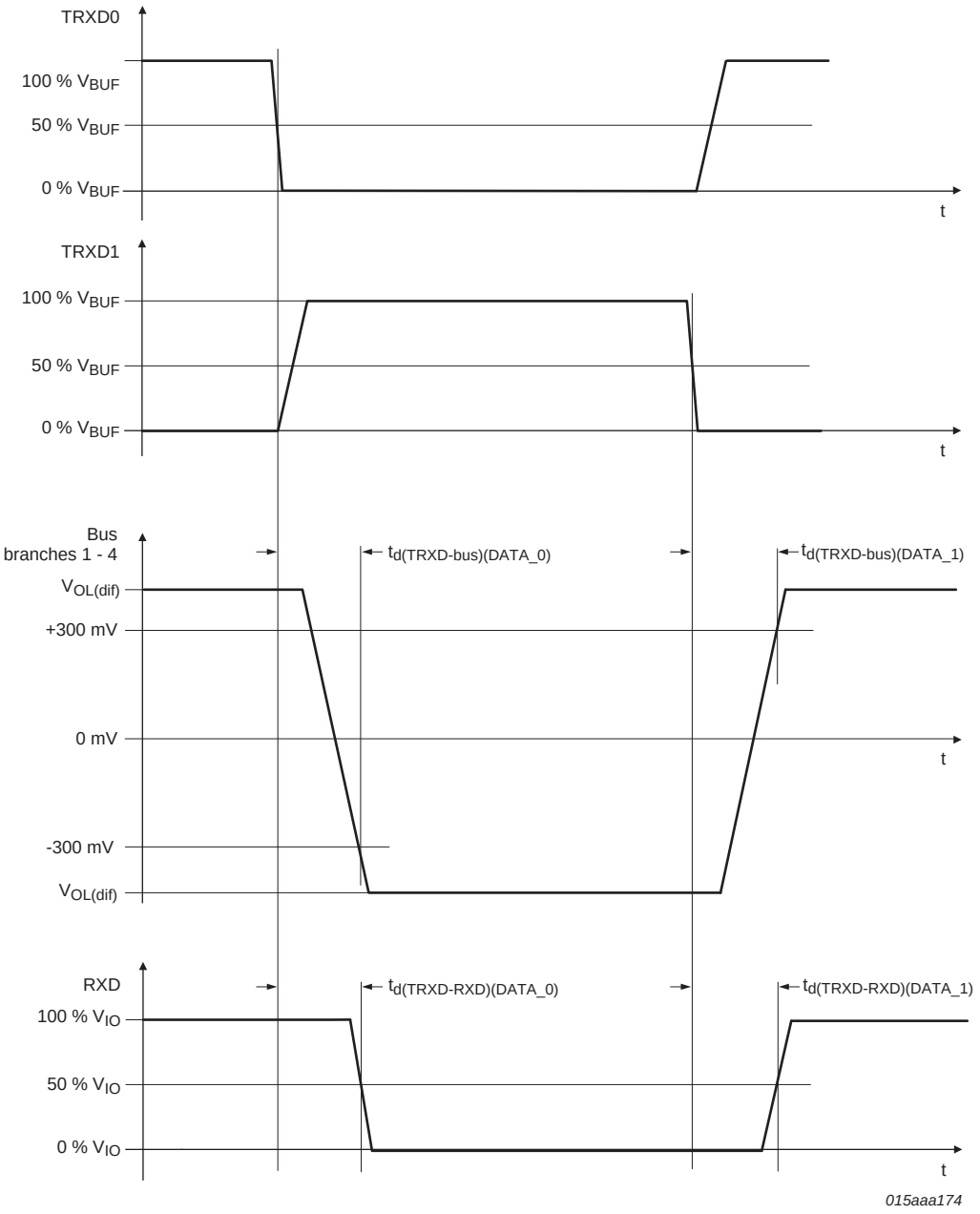


Fig 12. Timing diagram when the internal bus (TRXD0/1) is the input channel

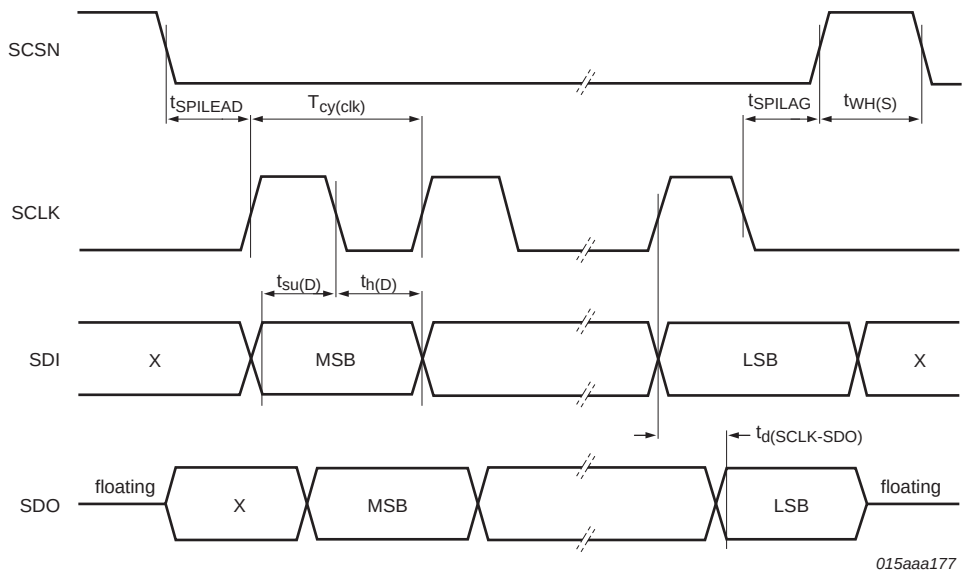


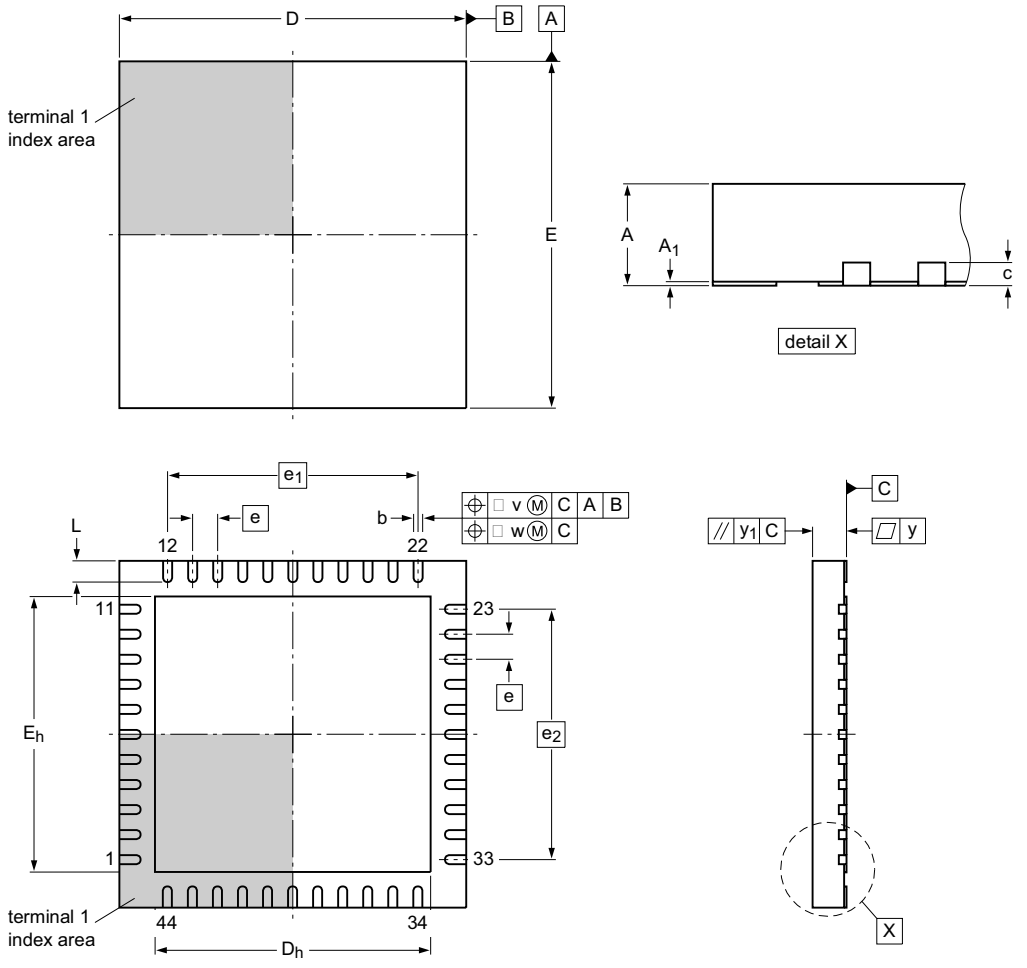
Fig 13. SPI timing

11. Application information

Further information on the application of the TJA1085 can be found in NXP application hints *AH1001_v1.0_TJA1085 FlexRay Active Star Coupler.*

12. Package outline

HVQFN44: plastic thermal enhanced very thin quad flat package; no leads
44 terminals; body 9 x 9 x 0.85 mm **SOT1113-1**



Dimensions

Unit		$A^{(1)}$	A_1	b	c	$D^{(1)}$	D_h	$E^{(1)}$	E_h	e	e_1	e_2	L	v	w	y	y_1
	max	1.00	0.05	0.35		9.1	7.25	9.1	7.25				0.63				
mm	nom	0.85	0.03	0.30	0.2	9.0	7.15	9.0	7.15	0.65	6.5	6.5	0.55	0.1	0.05	0.08	01
	min	0.80	0.00	0.25		8.9	7.05	8.9	7.05				0.47				

Note
1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

sot1113-1_po

Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOT1113-1	---	---	---		~~09-07-17~~ 10-07-23

Fig 14. Package outline SOT1113-1 (HVQFN44)

13. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

13.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

13.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

13.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

13.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see Figure 15) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 16 and 17

Table 16. SnPb eutectic process (from J-STD-020D)

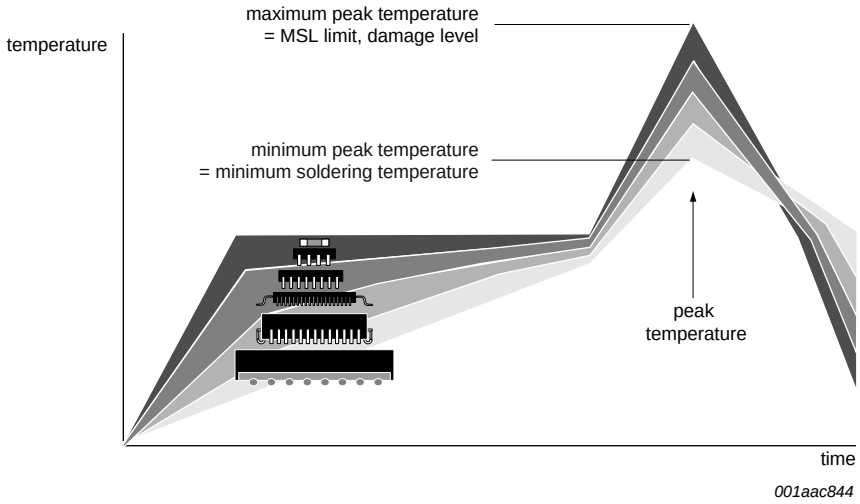
Package thickness (mm)	Package reflow temperature (°C)	
	Volume (mm^3)	
	< 350	≥ 350
< 2.5	235	220
≥ 2.5	220	220

Table 17. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm^3)		
	< 350	350 to 2000	> 2000
< 1.6	260	260	260
1.6 to 2.5	260	250	245
> 2.5	250	245	245

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 15.



MSL: Moisture Sensitivity Level

Fig 15. Temperature profiles for large and small components

For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

14. Appendix: EPL 3.0.1/ISO17458-4 to TJA1085 parameter conversion

Table 18. EPL 3.0.1/ISO17458-4 to TJA1085 conversion

EPL 3.0.1				TJA1085			
Symbol	**Min**	**Max**	**Unit**	**Symbol**	**Min**	**Max**	**Unit**
dBusTx01	6	18.75	ns	$t_{r(dif)(bus)}$	6	18.75	ns
dBusTx10	6	18.75	ns	$t_{f(dif)(bus)}$	6	18.75	ns
uStarTxactive	600	2000	mV	$\|V_{OH(dif)}\|$, $\|V_{OL(dif)}\|$	900	2000	mV
uStarTxidle	0	30	mV	$\|V_{o(idle)(dif)}\|$	0	25	mV
dBranchRxActiveMax	650	2600	µs	$t_{detCL(bus)}$	650	2600	µs
R_{CM1}, R_{CM2}	10	40	kΩ	R_i (pins BP and BM)	10	40	kΩ
uCM	−10	+15	V	V_{cm}[1]	−10	+15	V
$uStarUVV_{BAT}$	4	5.5	V	$V_{uvd(VBAT)}$	4.45	4.715	V
$uStarUVV_{CC}$	4	-	V	$V_{uvd(VCC)}$	4.45	4.715	V
$dStarUVV_{CC}$	-	1000	ms	$t_{det(uv)(VCC)}$	5	100	µs
iBP_{Leak}	-	25	µA	$\|I_{LI(BP)}\|$	-	5	µA
iBM_{Leak}	-	25	µA	$\|I_{LI(BM)}\|$	-	5	µA
$iBM_{GNDShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BM)	-	60	mA
$iBP_{GNDShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BP)	-	60	mA
$iBM_{BAT48ShortMax}$	-	72	mA	$\|I_{O(sc)}\|$ (pin BM)	-	72	mA
$iBP_{BAT48ShortMax}$	-	72	mA	$\|I_{O(sc)}\|$ (pin BP)	-	72	mA
$iBM_{BAT27ShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BM)	-	60	mA
$iBP_{BAT27ShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BP)	-	60	mA
functional class: Active Star - bus guardian interface				implemented (see Section 2.4)			
dStarDelay10	-	150	ns	$t_{d(bus-TRXD)} + t_{d(TRXD-bus)}$	-	150	ns
dStarDelay01	-	150	ns	$t_{d(bus-TRXD)} + t_{d(TRXD-bus)}$	-	150	ns
dStarAsym	0	8	ns	$\|\Delta t_{d(bus-bus)}\|$	-	8	ns
dStarAsym2	0	10	ns	$\|\Delta t_{d(bus-TRXD)}\| + \|\Delta t_{d(TRXD-bus)}\|$	-	10	ns
dStarSetUpDelay	-	500	ns	$t_{det(act)(TXEN)} + t_{d(TXD-TRXD)}$	20	110	ns
				$t_{det(act)(bus)} + t_{d(bus-TRXD)}$	100	285	ns
dStarGoToSleep	640	6400	ms	$t_{to\_stargotosleep}$	640	6400	ms
dStarWakeupReactionTime	-	70	µs	$t_{d(bus)(wake-act)}$	-	18	µs
device qualification according to AEC-Q100 (Rev. F)				see Section 2.1			
T_{AMB_Class1}	−40	+125	°C	T_{amb}	−40	+125	°C
$iBM_{-5VshortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BM)	-	60	mA
$iBP_{-5VshortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (pin BP)	-	60	mA
functional class: Active Star - voltage regulator control				implemented (see Section 2.4)			
$iBM_{BPShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (BP to BM)	-	60	mA
$iBP_{BMShortMax}$	-	60	mA	$\|I_{O(sc)}\|$ (BM to BP)	-	60	mA
$iBM_{BAT60ShortMax}$	-	90	mA	$\|I_{O(sc)}\|$ (pin BP)	-	72	mA
$iBP_{BAT60ShortMax}$	-	90	mA	$\|I_{O(sc)}\|$ (pin BM)	-	72	mA
uBias - Non-Low Power	1800	3200	mV	$V_{o(idle)(BP)}$, $V_{o(idle)(BM)}$[2]	1800	3150	mV
uBias - Low Power	−200	+200	mV	$V_{o(idle)(BP)}$, $V_{o(idle)(BM)}$[3]	−100	+100	mV

Table 18. EPL 3.0.1/ISO17458-4 to TJA1085 conversion *...continued*

EPL 3.0.1				TJA1085			
Symbol	**Min**	**Max**	**Unit**	**Symbol**	**Min**	**Max**	**Unit**
$dStarUVV_{BAT}$	-	1000	ms	$t_{det(uv)(VBAT)}$	5	150	µs
$uStarUVV_{IO}$	2	-	V	$V_{uvd(VIO)}$	2.55	2.765	V
$dStarUVV_{IO}$	-	1000	ms	$t_{det(uv)(VIO)}$	5	100	µs
$uINH1_{Not\_Sleep}$	uVBAT − 1 V	-	V	V_{OH} (pin INH)	V_{BAT} − 0.8 V	V_{BAT}	V
$iINH1_{Leak}$	-	10	µA	I_L (pin INH)	−3	+3	µA
dStarTSSLengthChange	−450	0	ns	$-(t_{det(act)(bus)} + t_{det(act)(TRXD)})$	−410	-	ns
				$-t_{det(act)(bus)}$	-	−100	ns
dStarFES1LengthChange	0	450	ns	$t_{det(idle)(bus)}$	100	-	ns
				$t_{det(idle)(bus)} + t_{det(idle)(TRXD)}$	-	400	ns
$dStarUVV_{Supply}$	-	1	ms	$t_{det(uv)(VBUF)}$	5	100	µs
$dStarRV_{Supply}$	-	10	ms	$t_{rec(uv)(VBUF)}$	5	100	µs
$uStarUVV_{Supply}$	4	-	V	$V_{uvd(VBUF)}$	4.2	4.474	V
$dStarRV_{BAT}$	-	10	ms	$t_{rec(uv)(VBAT)}$	5	150	µs
$dStarRV_{CC}$	-	10	ms	$t_{rec(uv)(VCC)}$	5	100	µs
$dStarRV_{IO}$	-	10	ms	$t_{rec(uv)(VIO)}$	5	100	µs
$dWU_{Interrupt}$	0.13	1	µs	$t_{sup(int)wake}$	130	1000	ns
$dWU_{0Detect}$	1	4	µs	$t_{det(wake)DATA\_0}$	1	4	µs
$dWU_{IdleDetect}$	1	4	µs	$t_{det(wake)idle}$	1	4	µs
$dWU_{Timeout}$	48	140	µs	$t_{det(wake)tot}$	50	115	µs
dStarWakePulseFilter	1	500	µs	$t_{det(wake)(LWU)}$	2.9	175	µs
$iBP_{LeakGND}$	-	1600	µA	$\|I_{LI(BP)}\|$	-	1600	µA
$iBM_{LeakGND}$	-	1600	µA	$\|I_{LI(BM)}\|$	-	1600	µA
$dStarWakeupReaction_{local}$	-	100	µs	$t_{d(LWUwake-INHH)}$	0	100	µs
dStarSymbolLengthChange	−300	+450	ns	$\Delta t_{det(act-idle)(bus)} + \Delta t_{det(act-idle)(TRXD)}$	−100	+100	ns
functional class: Active Star - logic level adaptation				implemented (see Section 2.4)			
functional class: Active Star - increased voltage amplitude transmitter				implemented (see Section 2.4)			
$uESD_{EXT}$	6	-	kV	$\|V_{ESD}\|$: HBM on pins BP and BM to GND	8	-	kV
				$\|V_{ESD}\|$: HBM on pins LWU and V_{BAT} to GND	6	-	kV
$uESD_{INT}$	2	-	kV	$\|V_{ESD}\|$ (HBM on any other pin)	4	-	kV
$uESD_{IEC}$	6	-	kV	IEC61000-4-2 on pins BP and BM to GND	6	-	kV
$uV_{BAT-WAKE}$	-	7	V	V_{BAT}	4.75	60	V
dBusTxai	-	30	ns	$t_{r(dif)(bus)}$ (DATA_0 to idle)	-	30	ns
dBusTxia	-	30	ns	$t_{f(dif)(bus)}$ (idle to DATA_0)	-	30	ns
valid operating modes when $V_{StarSupply}$ = nominal; $V_{BAT} \geq$ 7 V; V_{CC} = nominal				AS_Sleep, AS_Standby, AS_Normal			

Table 18. EPL 3.0.1/ISO17458-4 to TJA1085 conversion *...continued*

EPL 3.0.1				TJA1085			
Symbol	**Min**	**Max**	**Unit**	**Symbol**	**Min**	**Max**	**Unit**
valid operating modes when $V_{StarSupply}$ = nominal; $V_{BAT} \geq$ 5.5 V; V_{CC} = nominal				AS_Sleep, AS_Standby, AS_Normal			
dBusTxDif	-	3	ns	$\lvert\Delta t_{(r\text{-}f)(dif)}\rvert$	-	3	ns
$R_{StarTransmitter}$	product-specific			$Z_{o(eq)(TX)}$	10	600	Ω
dStarSymbolEndLengthChange	0	450	ns	$t_{det(idle)(bus)}$	100	-	ns
				$t_{det(idle)(bus)} + t_{det(idle)(TRXD)}$	-	400	ns
Active star with communication controller interface							
dStarRxAsym	-	10	ns	$\lvert\Delta t_{d(bus\text{-}TRXD)}\rvert + \lvert\Delta t_{d(TRXD\text{-}RXD)}\rvert$	-	10	ns
dStarRx10	-	225	ns	$t_{d(bus\text{-}TRXD)} + t_{d(TRXD\text{-}RXD)}$	-	135	ns
dStarRx01	-	225	ns	$t_{d(bus\text{-}TRXD)} + t_{d(TRXD\text{-}RXD)}$	-	135	ns
dStarRxai	50	550	ns	$t_{det(idle)(bus)} + t_{d(bus\text{-}RXD)}$	100	-	ns
				$t_{det(idle)(bus)} + t_{d(bus\text{-}TRXD)} + t_{det(idle)(TRXD)} + t_{d(TRXD\text{-}RXD)}$	-	535	ns
dStarRxia	100	550	ns	$t_{det(act)(bus)} + t_{d(bus\text{-}RXD)}$	100	-	ns
				$t_{det(act)(bus)} + t_{d(bus\text{-}TRXD)} + t_{det(act)(TRXD)} + t_{d(TRXD\text{-}RXD)}$	-	545	ns
dStarTxAsym	-	10	ns	$\lvert\Delta t_{d(TXD\text{-}TRXD)}\rvert + \Delta\lvert t_{d(TRXD\text{-}bus)}\rvert$	-	10	ns
dStarTx10	-	225	ns	$t_{d(TXD\text{-}TRXD)} + t_{d(TRXD\text{-}bus)}$	-	135	ns
dStarTx01	-	225	ns	$t_{d(TXD\text{-}TRXD)} + t_{d(TRXD\text{-}bus)}$	-	135	ns
dStarTxai	-	550	ns	$t_{det(idle)(TXEN)} + t_{d(TXD\text{-}TRXD)} + t_{det(idle)(TRXD)} + t_{d(TRXD\text{-}bus)}$	-	385	ns
dStarTxia	-	550	ns	$t_{det(act)(TXEN)} + t_{d(TXD\text{-}TRXD)} + t_{det(act)(TRXD)} + t_{d(TRXD\text{-}bus)}$	-	385	ns
$uV_{DIG\text{-}OUT\text{-}HIGH}$	80	100	%	V_{OH} (pin RXD)	V_{IO} – 0.4	V_{IO}	V
$uV_{DIG\text{-}OUT\text{-}LOW}$	-	20	%	V_{OL} (pin RXD)	-	0.4	V
$uV_{DIG\text{-}IN\text{-}HIGH}$	-	70	%	V_{IH} (pins TXEN and BGE)	$0.7V_{IO}$	5.5	V
$uV_{DIG\text{-}IN\text{-}LOW}$	30	-	%	V_{IL} (pins TXEN and BGE)	–0.3	$0.3V_{IO}$	V
uData0	–300	–150	mV	$V_{IL(dif)}$ (pins BP and BM)	–300	–150	mV
uData1	150	300	mV	$V_{IH(dif)}$ (pins BP and BM)	150	300	mV
uData1 - |uData0|	–30	+30	mV	$\Delta V_{i(dif)(H\text{-}L)}$	–30	+30	mV
uStarLogic_1	-	60	%	V_{IH} (pin TXD)	$0.6V_{IO}$	5.5	V
uStarLogic_0	40	-	%	V_{IL} (pin TXD)	–0.3	$0.4V_{IO}$	V
$dStarRxD_{R15}$ + $dStarRxD_{F15}$	-	13	ns	$t_{(r+f)}$ (pin RXD)	-	13	ns
functional class: Active Star - communication controller interface				implemented			
dStarTxRxai	-	325	ns	$t_{d(TXEN\text{-}RXD)}$	-	150	ns
C_StarTxD	-	10	pF	C_i (pin TXD)	-	10	pF
$uV_{DIG\text{-}OUT\text{-}UV}$	-	500	mV	V_O (pin RXD)[4]	-	500	mV
uData0_LP	–400	–100	mV	$V_{IL(dif)}$ (pins BP and BM)	–400	–125	mV
$uV_{DIG\text{-}OUT\text{-}OFF}$	product specific			V_O (pin RXD)[5]	V_{IO} – 500	V_{IO}	mV

Table 18. EPL 3.0.1/ISO17458-4 to TJA1085 conversion *...continued*

EPL 3.0.1				TJA1085			
Symbol	**Min**	**Max**	**Unit**	**Symbol**	**Min**	**Max**	**Unit**
dStarTSSLengthChange_TxD_Bus	–450	0	ns	$-(t_{det(act)(TXEN)} + t_{det(act)(TRXD)})$	–250	-	ns
				$-t_{det(act)(TXEN)}$	-	–20	ns
dStarFES1LengthChange_TxD_Bus	0	450	ns	$t_{det(idle)(TXEN)}$	20	-	ns
				$t_{det(idle)(TXEN)} + t_{det(idle)(TRXD)}$	-	250	ns
dStarSymbolLengthChange_TxD_Bus	–300	+400	ns	$\Delta t_{det(act-idle)(TXEN)} + \Delta t_{det(act-idle)(TRXD)}$	–75	+75	ns
dStarTSSLengthChange_Bus_RxD	–450	0	ns	$-(t_{det(act)(bus)} + t_{det(act)(TRXD)})$	–410	-	ns
				$-t_{det(act)(bus)}$	-	–100	ns
dStarFES1LengthChange_Bus_RxD	0	450	ns	$t_{det(idle)(bus)}$	100	-	ns
				$t_{det(idle)(bus)} + t_{det(idle)(TRXD)}$	-	400	ns
dStarSymbolLengthChange_Bus_RxD	–300	+400	ns	$\Delta t_{det(act-idle)(bus)} + \Delta t_{det(act-idle)(TRXD)}$	–100	+100	ns
dStarActivityDetection	100	250	ns	$t_{det(act)(bus)}$	100	210	ns
dStarIdleDetection	50	200	ns	$t_{det(idle)(bus)}$	100	200	ns
$\lvert dStarRxD_{R15} - dStarRxD_{F15} \rvert$	-	5	ns	$\lvert\Delta t_{(r-f)}\rvert$ (pin RXD)	-	5	ns
dStarTxActiveMax	650	2600	µs	$t_{detCL(TXEN)}$	650	2600	µs
$dStarTx_{reaction}$	-	75	ns	$t_{det(idle)(TXEN)}$	20	50	ns
Active Star with host interface							
$dStarModeChange_{SPI}$	-	100	µs	$t_{t(moch)}$	-	25	µs
$dStarReactionTime_{SPI}$	-	200	µs	$t_{det(int)}$	-	100	µs
$uV_{DIG-OUT-HIGH}$	80	100	%	V_{OH} (pin SDO)	V_{IO} – 0.4	V_{IO}	V
$uV_{DIG-OUT-LOW}$	-	20	%	V_{OL} (pins SDO, INTN)	-	0.4	V
$uV_{DIG-IN-HIGH}$	-	70	%	V_{IH} (pins SDI, SCSN, SCLK)	$0.7V_{IO}$	5.5	V
$uV_{DIG-IN-LOW}$	30	-	%	V_{IL} (pins SDI, SCSN, SCLK)	–0.3	$0.3V_{IO}$	V
Functional class: Active Star - host interface				implemented			
SPI	0.01	1	Mbit/s	$t_{cl(clk)}$	0.5	100	µs
$uV_{DIG-OUT-UV}$	-	500	mV	V_O (pins SDO, INTN)[4]	-	500	mV
$uV_{DIG-OUT-OFF}$	product specific			V_O (pins SDO, INTN)[5]	-	500	mV
behavior when SCK not connected				pull-down behavior on SCLK			
behavior when SDI not connected				pull-down behavior on SDI			
behavior when SCSN not connected				pull-up behavior on SCSN			

[1] V_{cm} is the BP/BM common mode voltage, $(V_{BP} + V_{BM})/2$, and is specified in conditions column for parameters $V_{IH(dif)}$ and $V_{IL(dif)}$ for pins BP and BM; see Table 14. V_{cm} is tested on a receiving bus driver with a transmitting bus driver that has a ground offset voltage in the range –12.5 V to +12.5 V and transmits a 50/50 pattern.

[2] Min: $V_{o(idle)(BP)} = V_{o(idle)(BM)} = 0.4V_{BUF} = 0.4 \times 4.5\ V = 1800\ mV$; max value: $V_{o(idle)(BP)} = V_{o(idle)(BM)} = 0.6V_{BUF} = 0.6 \times 5.25\ V = 3150\ mV$; the nominal voltage is 2500 mV.

[3] The nominal voltage is 0 mV.

[4] When undervoltage on V_{IO}

[5] When $V_{CC} = V_{BAT} = V_{BUF} = 0$ V.

15. Abbreviations

Table 19. Abbreviations

Abbreviation	Description
AS	Active Star
CC	Communication Controller
ECU	Engine Control Unit
EMC	Electro Magnetic Compatibility
ESD	ElectroStatic Discharge

16. References

[1] **EPL —** FlexRay Communications System Electrical Physical Layer Specification Version 3.0.1, FlexRay Consortium

[2] **ISO 17458-4:2013 —** Road vehicles - FlexRay Communications System part 4: Electrical physical layer specification

17. Revision history

Table 20. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TJA1085 v.2	20160307	Product data sheet	-	TJA1085 v.1
Modifications:	• Section 1, Section 2.1, Section 14: text amended (specification updated) • Table 12: Table note 1 added; measurement conditions and table notes changed for parameter V_{ESD}; no time limit removed from measurement conditions throughout; table reformatted • Table 14: max. value changed for parameter I_{CC} • Section 11 added • Table 16, Table 17: JEDEC standard updated in table headers • Table 19 updated • Ref. 2 added			
TJA1085 v.1	20121023	Product data sheet	-	-

18. Legal information

18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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20. Contents

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